

**Elementary mechanisms of homoepitaxial
growth in MgO(001) :
from the isolated adsorbates to the complete monolayer**

Second ABINIT WORKSHOP, 10-12 May 2004

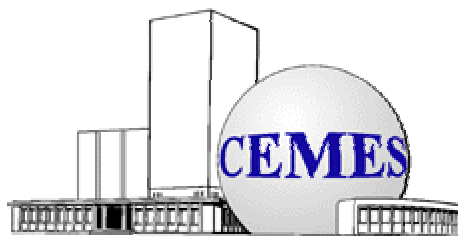
Grégory Geneste¹, Joseph Morillo², Fabio Finocchi³, Marc Hayoun⁴

¹ **Université de Liège**, Institut de physique, Allée du 6 Aout 17, 4000 Sart Tilman, Belgium

² **CEMES**, UPR CNRS 8011, 29 rue Jeanne Marvig, 31055 Toulouse, Cedex 4, France

³ **GPS**, Universités Paris 6 et 7, UMR CNRS 7588, Campus de Boucicaut, 140 rue de Lourmel,
75015 Paris, France

⁴ **LSI**, CEA/DSM/DRECAM, UMR CNRS 7642, Ecole Polytechnique, 91128 Palaiseau Cedex, France



Elementary mechanisms of crystal growth

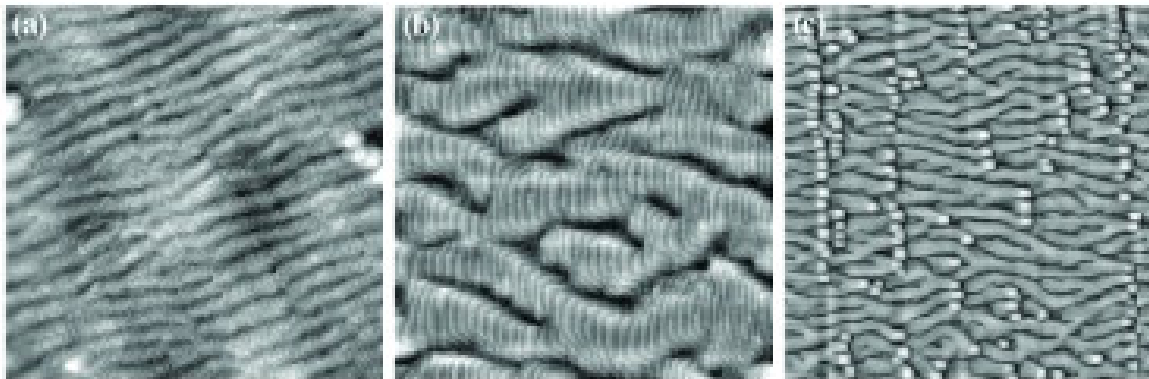
Crystal growth

Growth of metal oxides : unknown mechanisms
(compared to simple metals and semi-conductors)

Why studying the growth of oxides ?

Better control => Good quality surfaces/interfaces

Can growth instabilities in oxides lead to a spontaneous nanostructuring ?



« *Step-flow* » growth mode

Cu(100)

J. Neel et al,

J. Phys. Cond. Matter.

15 (2003), S3227-S3240

System and method

The system

MgO(001) : prototypical case

Method

a) DFT calculations : ABINIT

GGA-PBE

Troullier-Martins pseudopotentials

Slab geometry (4 layers) / Cut-off = 28 Hartrees

System size = 60-100 atoms

b) Classical Molecular Dynamics (« semi-empiric » potentials)
in the case of stoichiometric ionic systems

Overview

MgO growth : 3 phases

- 1 – Isolated species : Mg, O, O₂*
- 2 – Surface redox reactions
- 3 – Nucleation phenomena

Isolated species : *Mg atom*, O atom, O₂ molecule

Atomic Mg

Adsorption (physisorption)

Diffusion

Small clusters

Dissociation

Steps

Desorption

[010]

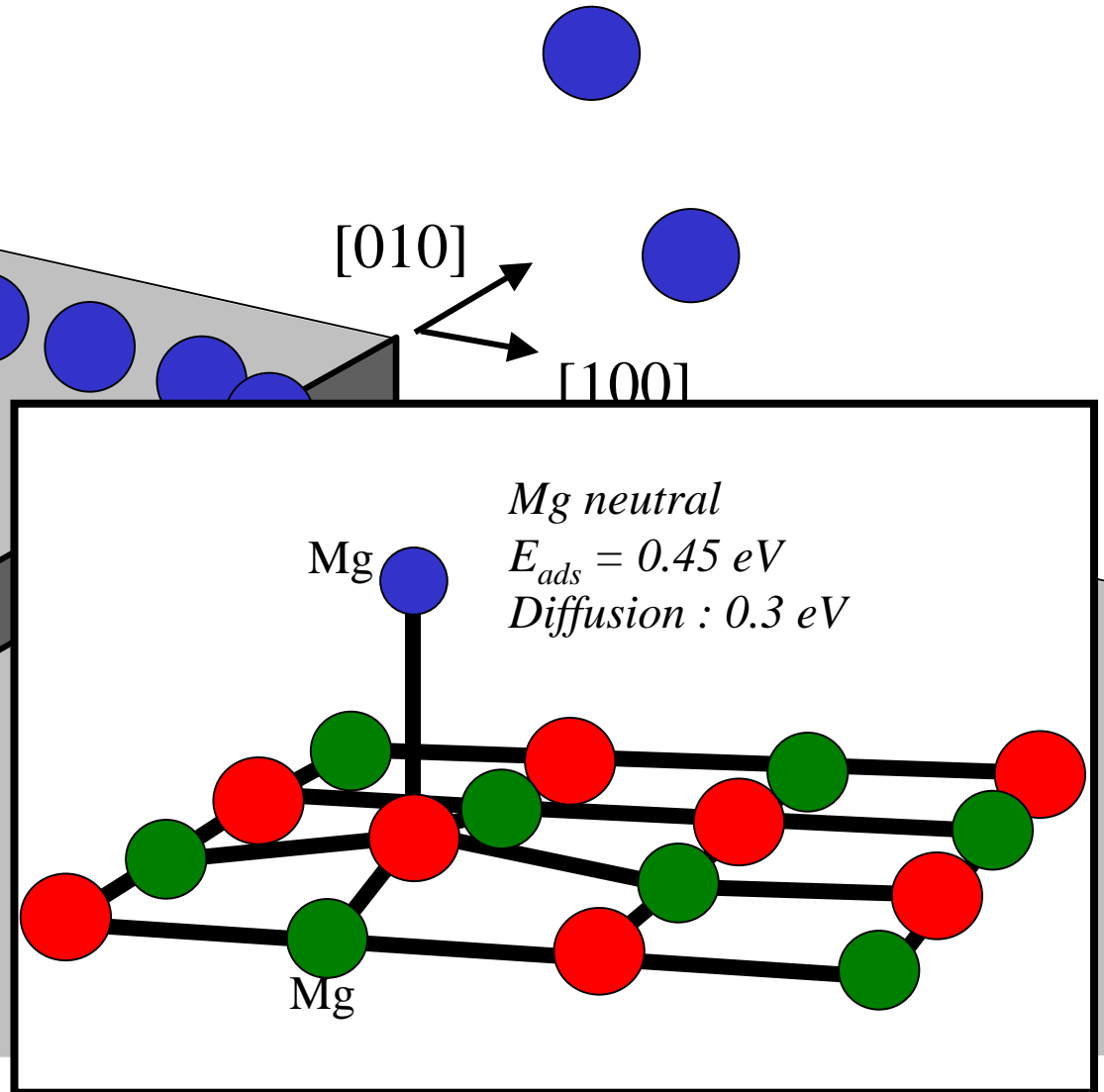
[100]

Mg neutral

$E_{ads} = 0.45 \text{ eV}$

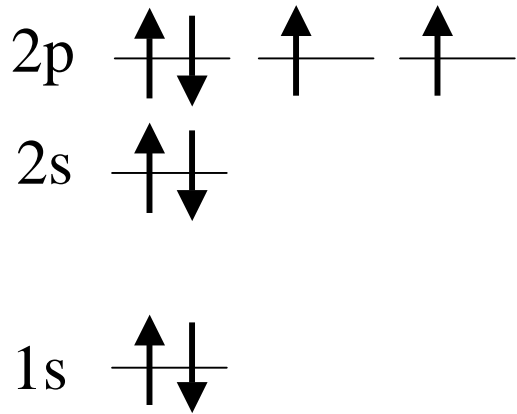
$\text{Diffusion} : 0.3 \text{ eV}$

... either they
bind to a step edge
 $\text{Attraction} / E_{binding} = 1 \text{ eV}$

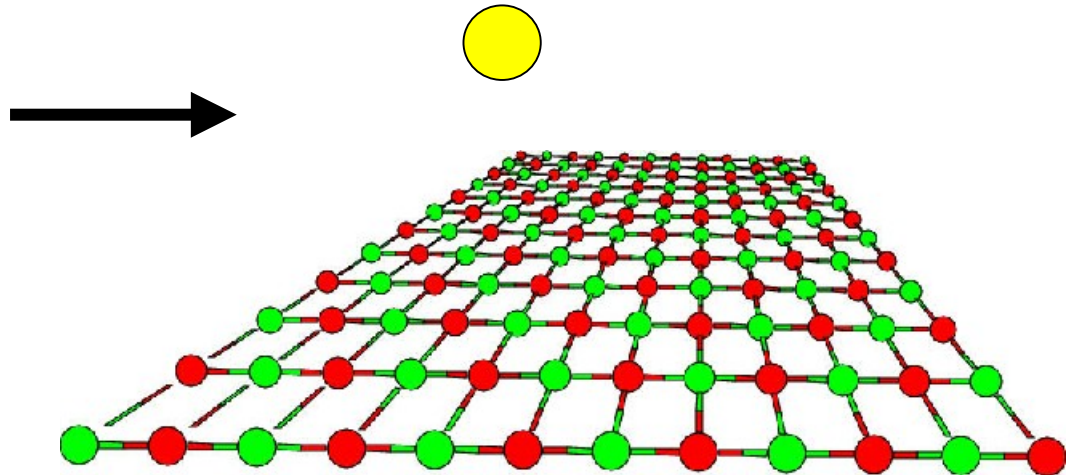


Isolated species : Mg atom, *O atom*, O₂ molecule

The free oxygen atom :



Adsorption on MgO(001):



Ground state : $S = 1$

Ground state : $S = ?$

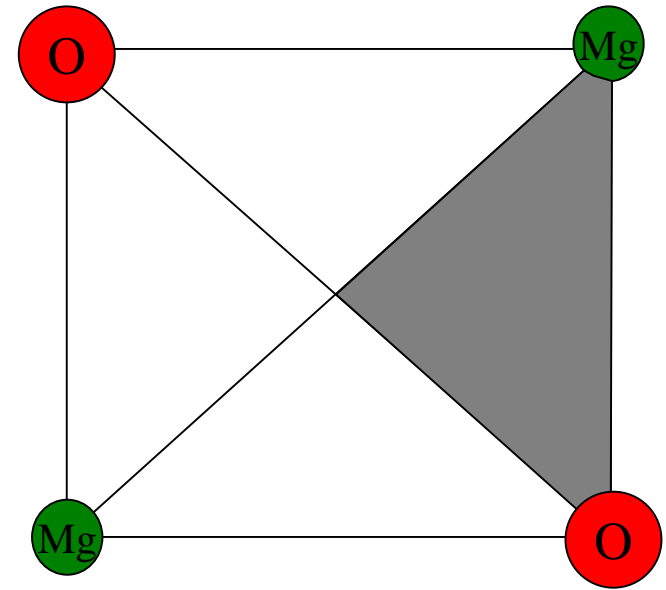
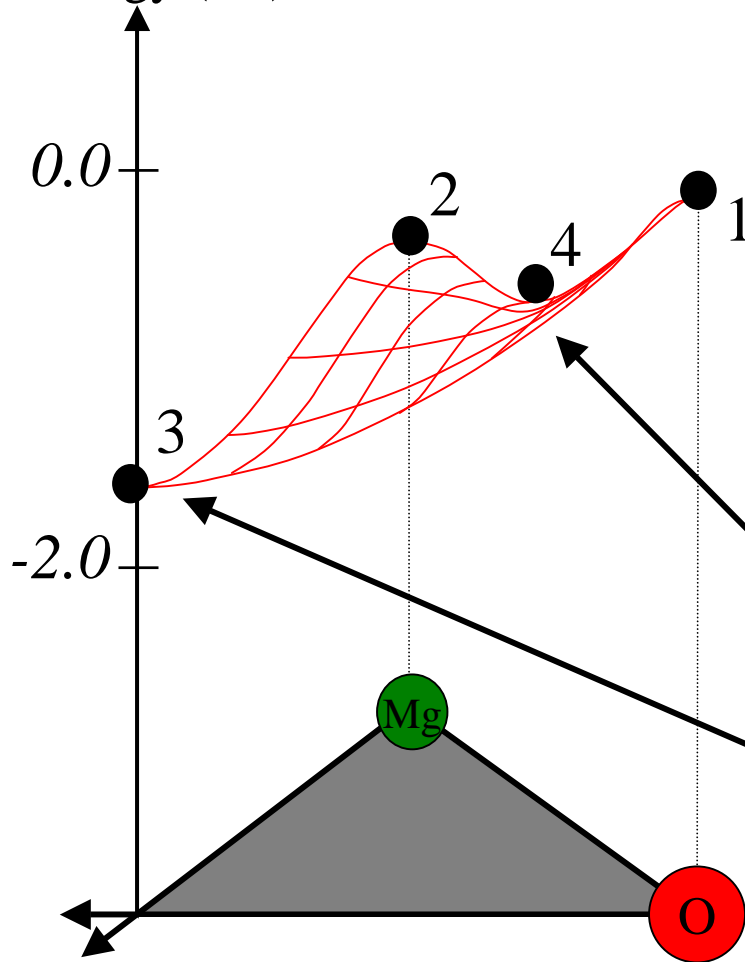
→ Depends on the adsorption site on the surface !

→ We computed TWO Born-Oppenheimer surfaces.

Isolated species : Mg atom, *O atom*, O₂ molecule

The Spin-polarized B.O. surface :

Total energy (eV)



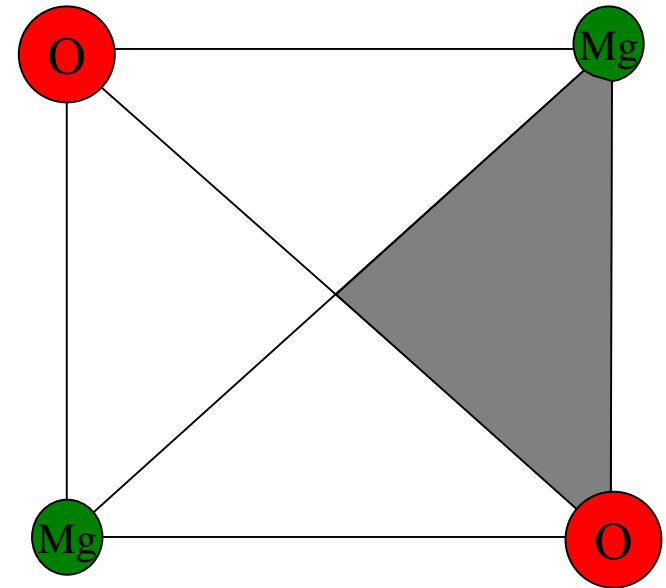
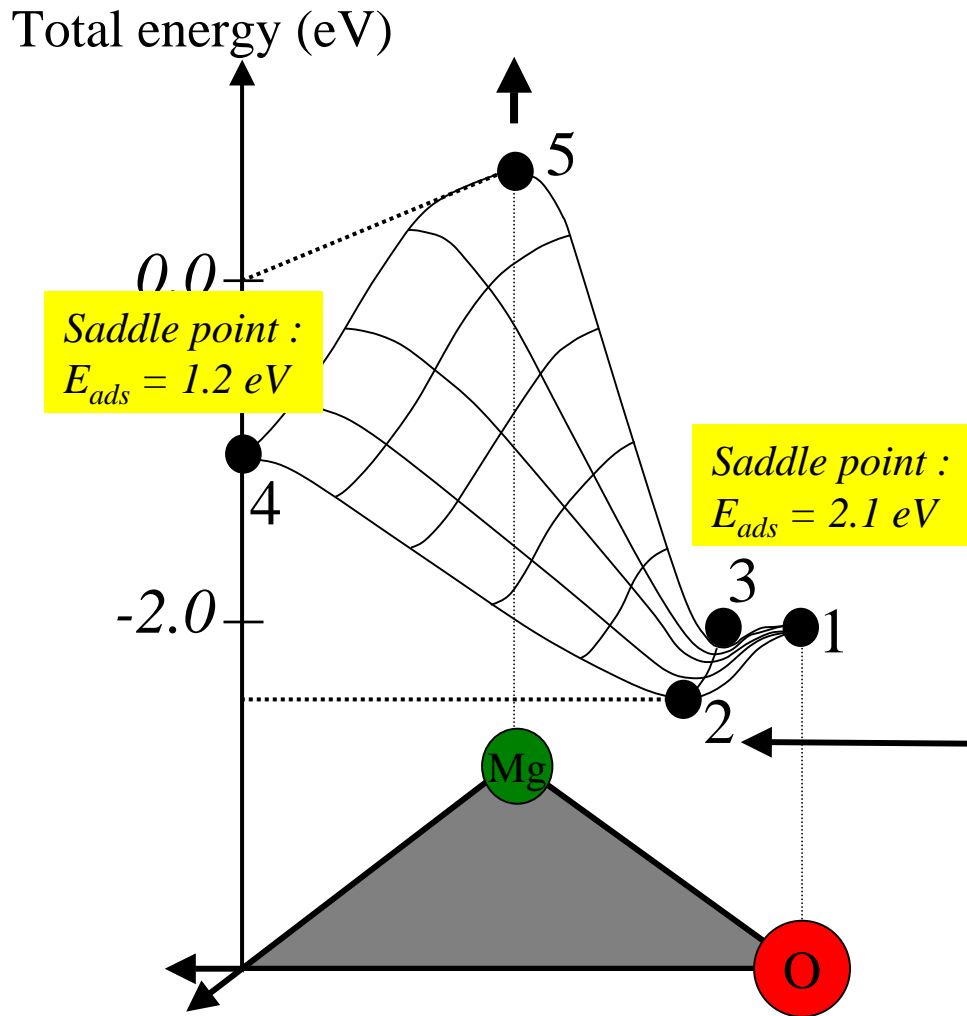
Surface unit cell : irreducible part

Saddle point : $E_{ads} = 1.1 \text{ eV}$

Minimum : $E_{ads} = 1.5 \text{ eV}$

Isolated species : Mg atom, *O atom*, O₂ molecule

The non spin-polarized B.O. surface :



Surface unit cell : irreducible part

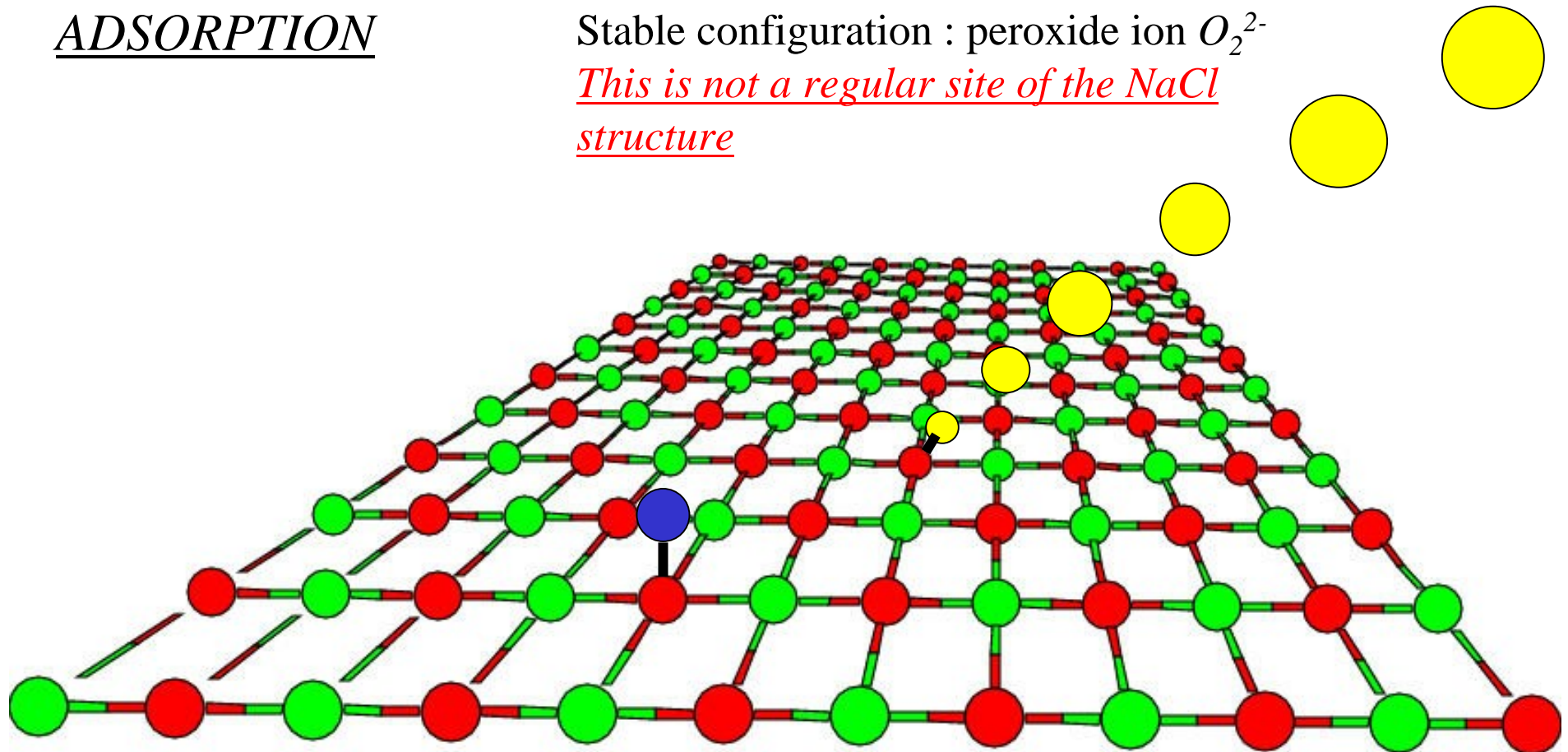
Minimum : $E_{ads} = 2.3 \text{ eV}$

The most stable configuration
Is not spin-polarized.
What is it ?

Isolated species : Mg atom, *O atom*, O₂ molecule

ADSORPTION

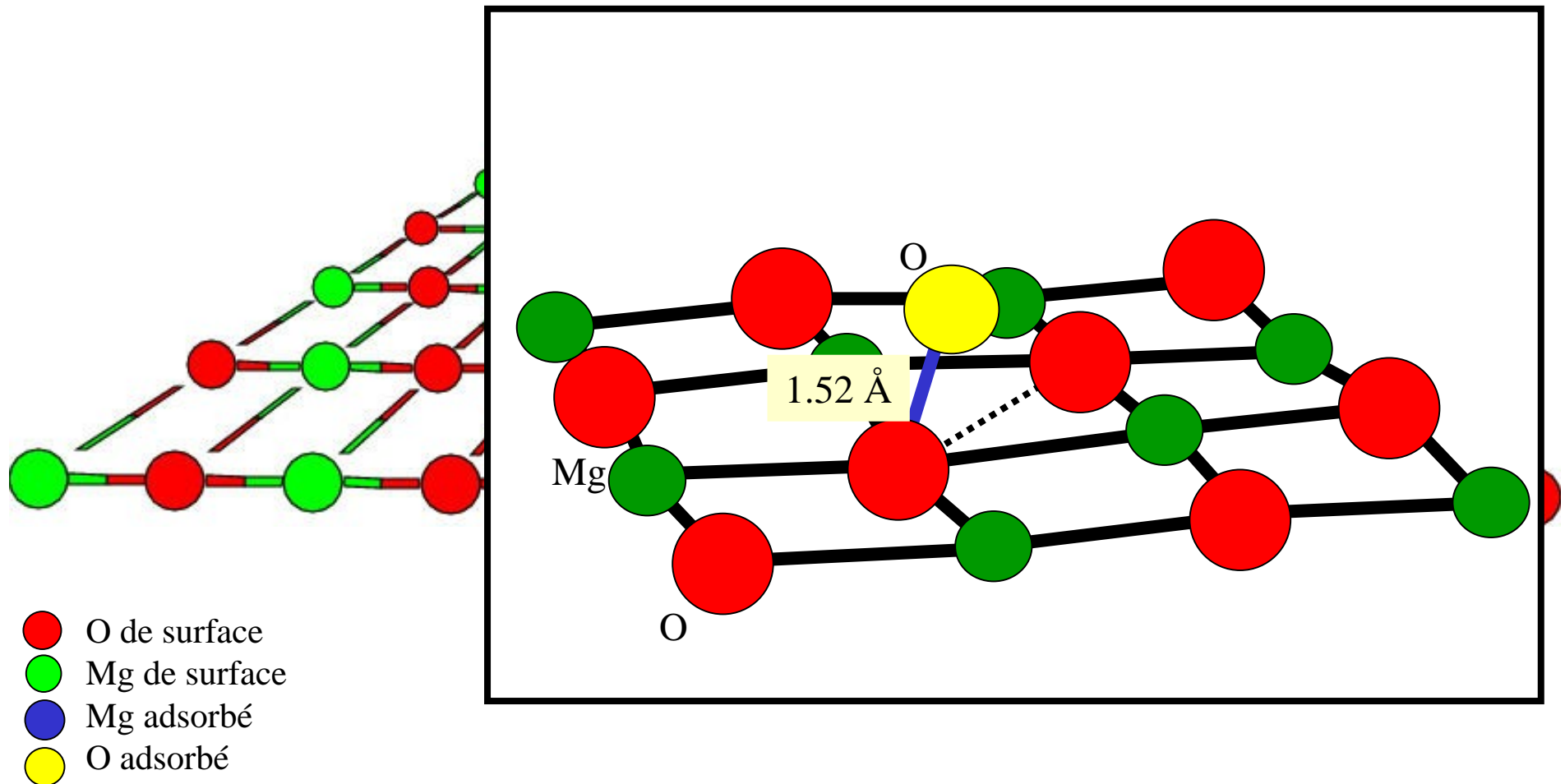
Stable configuration : peroxide ion O₂²⁻
This is not a regular site of the NaCl structure



Isolated species : Mg atom, *O atom*, O₂ molecule

ADSORPTION

Stable configuration : peroxide ion O₂²⁻
This is not a regular site of the NaCl structure

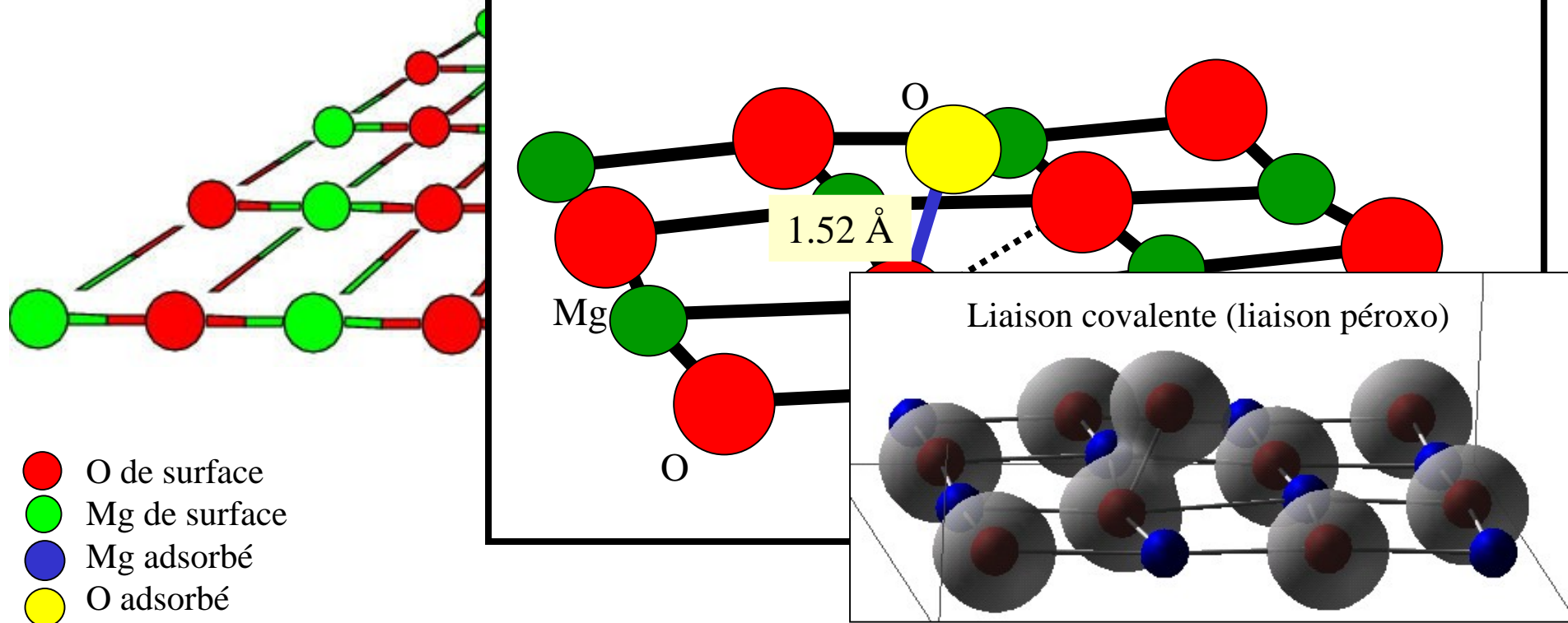


Isolated species : Mg atom, *O atom*, O₂ molecule

ADSORPTION

Stable configuration : peroxide ion O₂²⁻
This is not a regular site of the NaCl structure

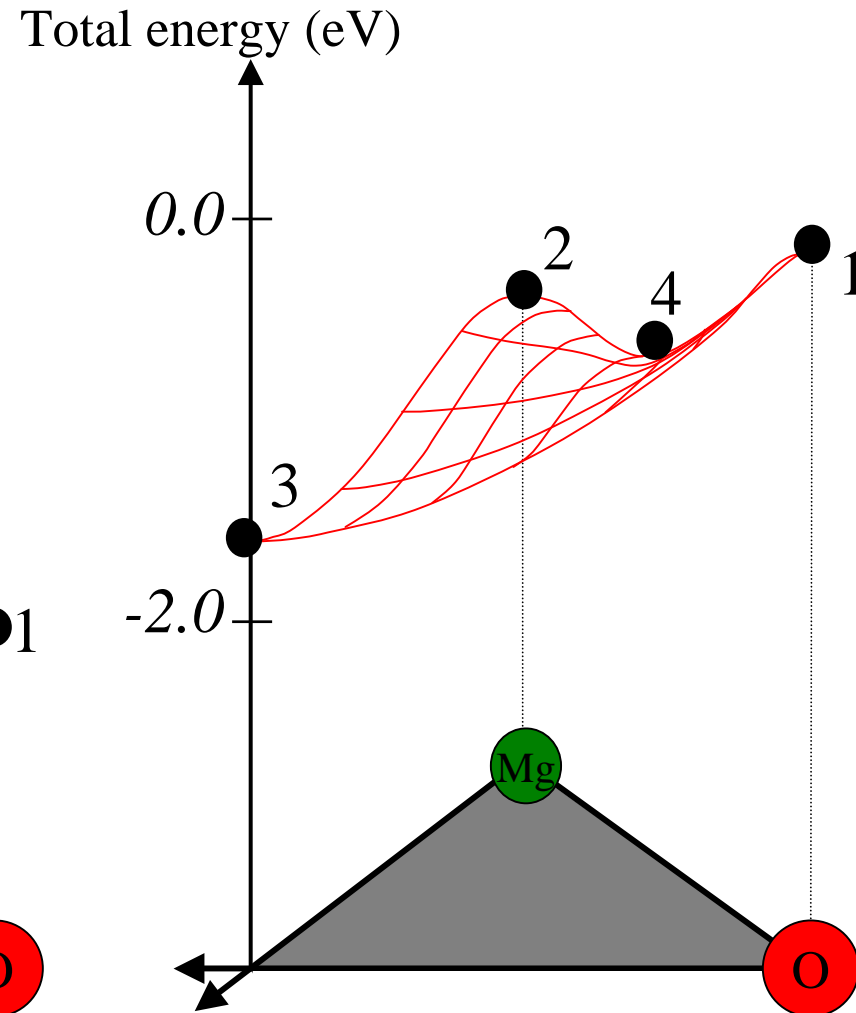
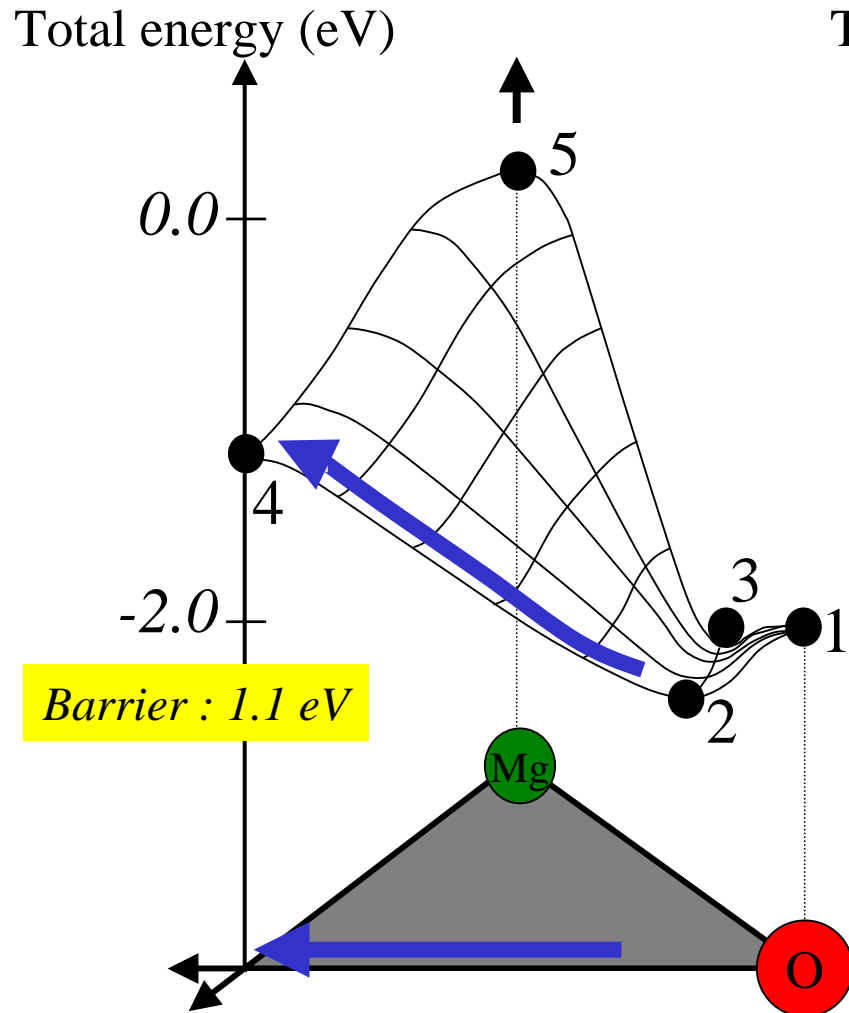
Strong interaction with
charge transfer
E_{ads} ~ 2.3 eV



Isolated species : Mg atom, *O atom*, O₂ molecule

DIFFUSION ?

3 saddle points => 3 possible movements

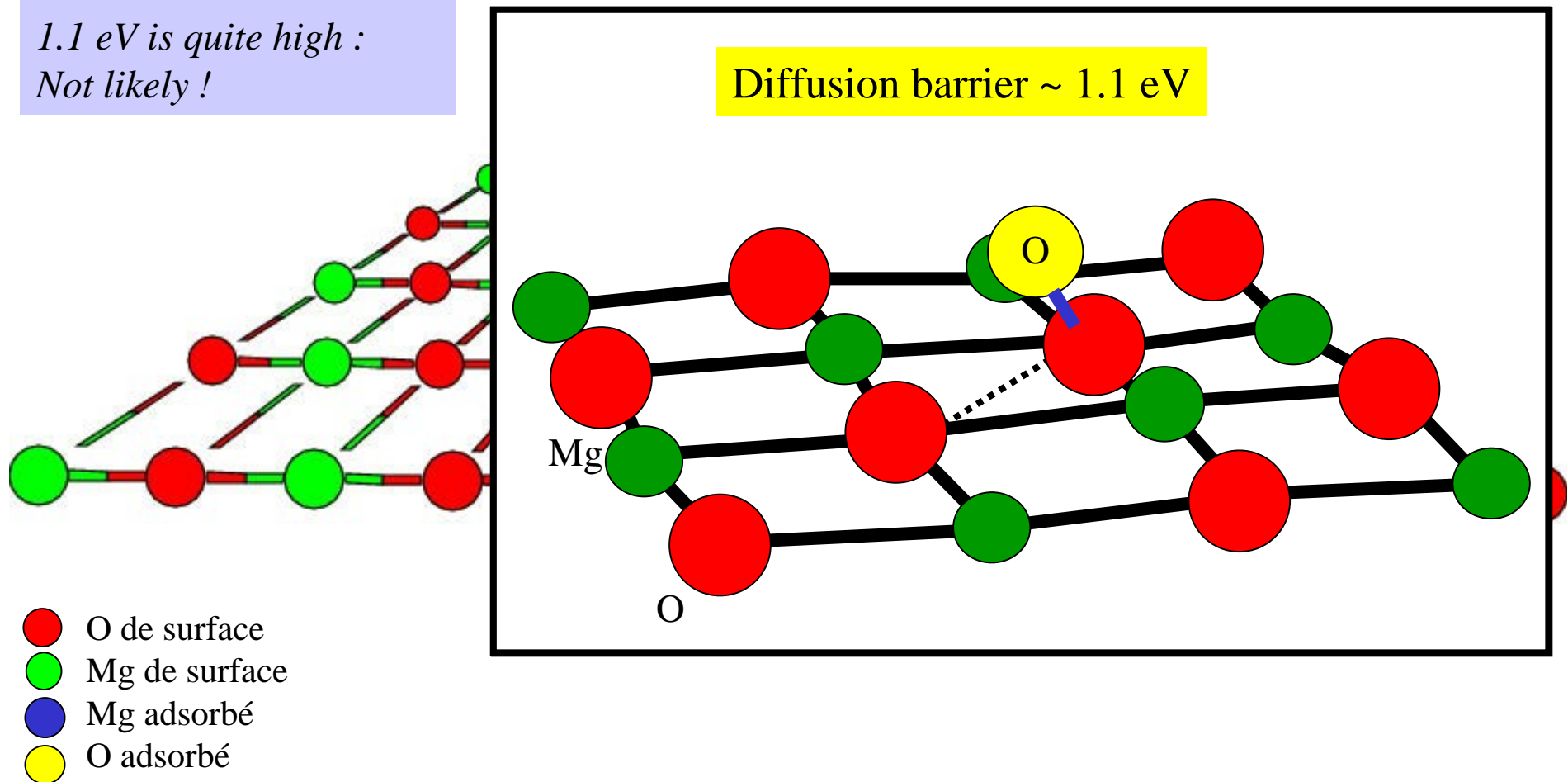


Isolated species : Mg atom, *O atom*, O₂ molecule

DIFFUSION

This movement implies to break the peroxy bond.

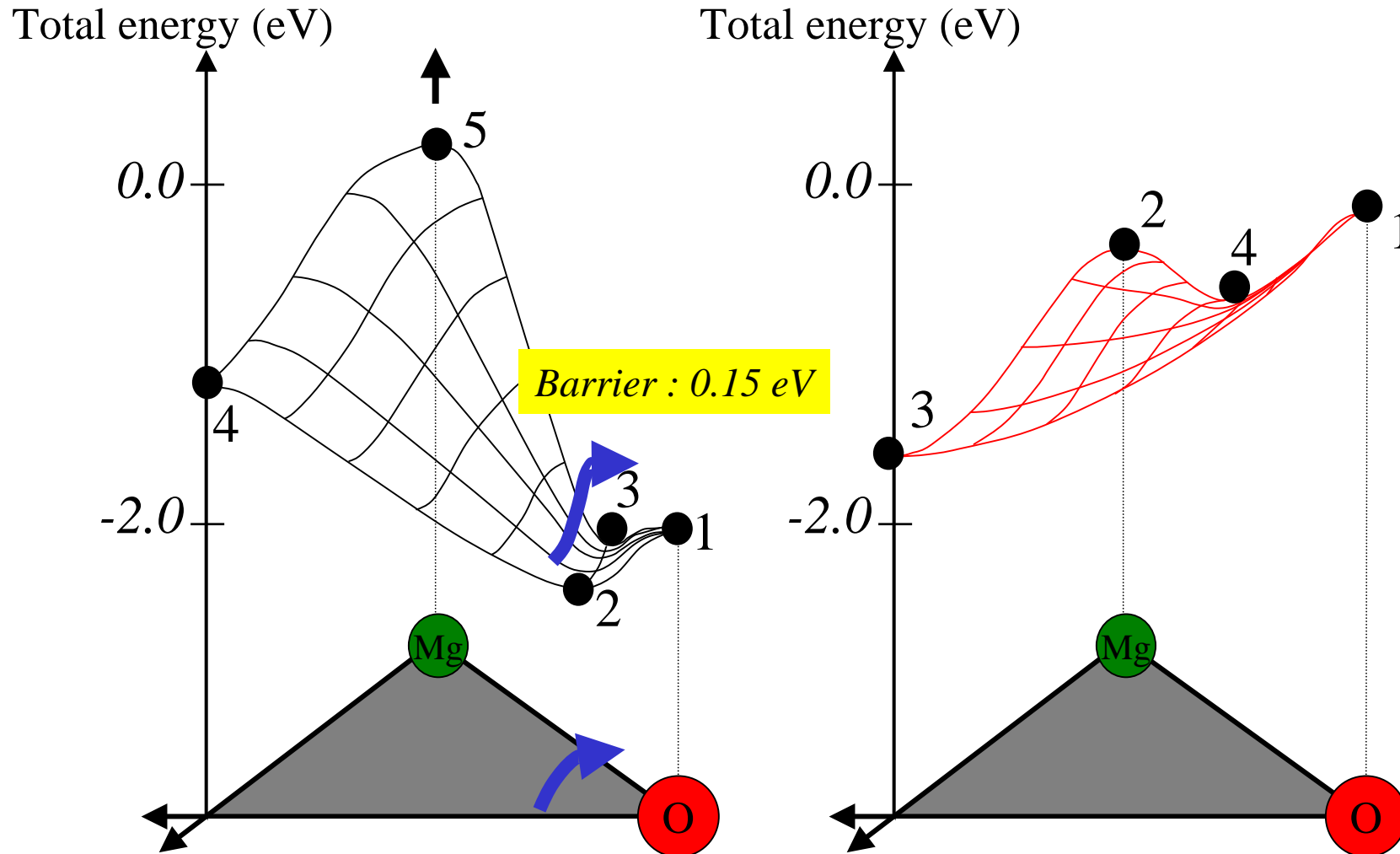
*1.1 eV is quite high :
Not likely !*



Isolated species : Mg atom, *O atom*, O₂ molecule

DIFFUSION ?

3 saddle points => 3 possible movements



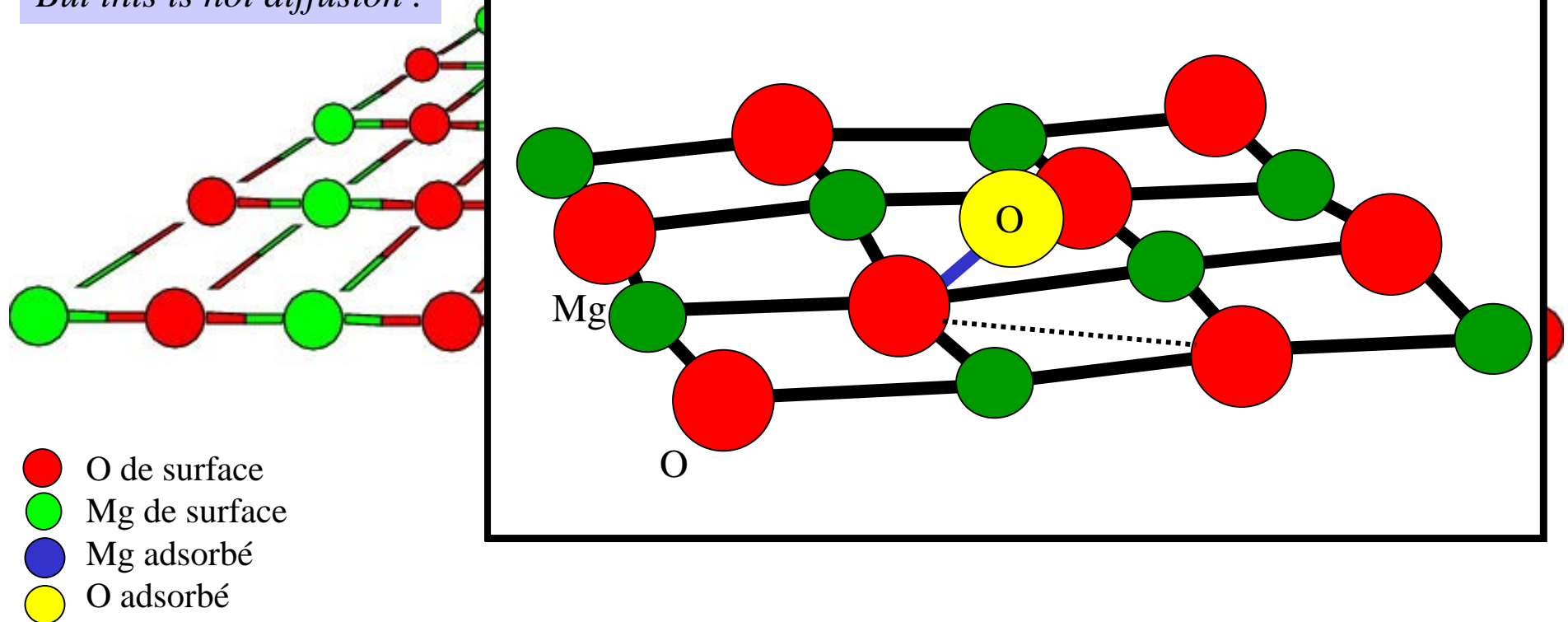
Isolated species : Mg atom, *O atom*, O₂ molecule

DIFFUSION

Rotation of the peroxide ion around its surface oxygen atom
Barrier ~ 0.15 eV

No need to break the peroxo bond.

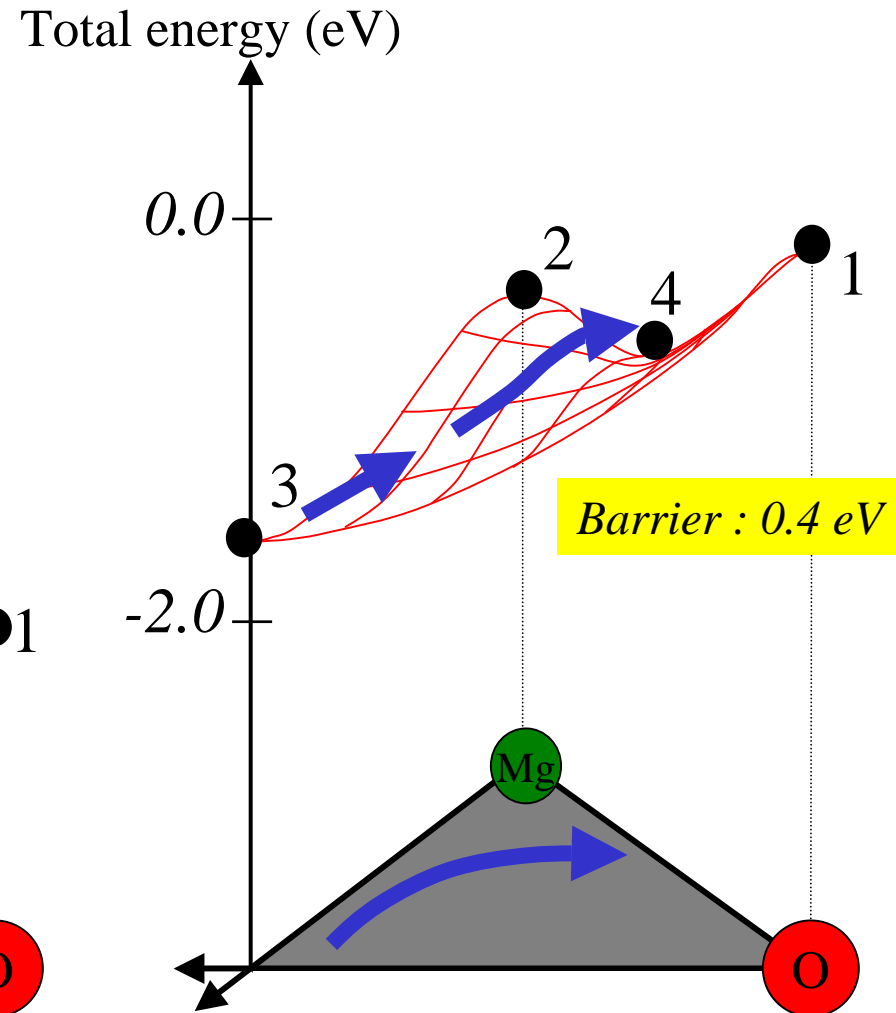
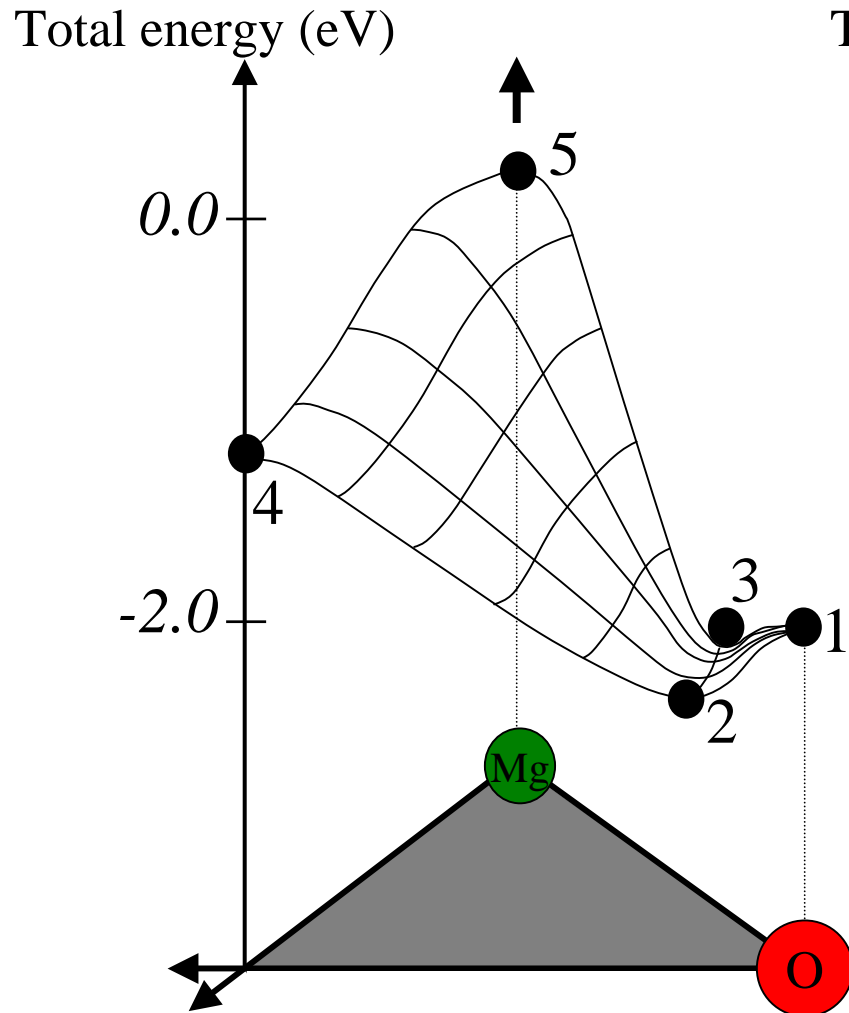
*Very likely !
But this is not diffusion !*



Isolated species : Mg atom, *O atom*, O₂ molecule

DIFFUSION ?

3 saddle points => 3 possible movements

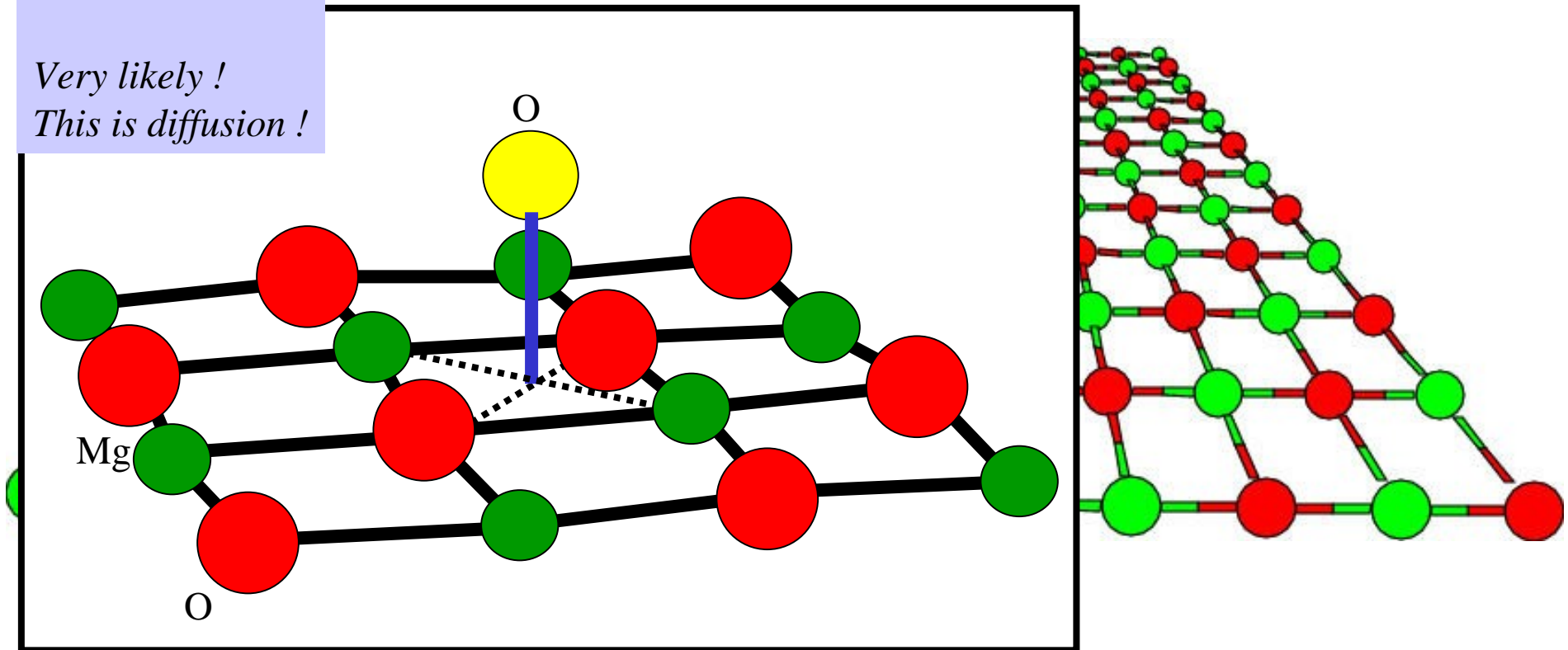


Isolated species : Mg atom, *O atom*, O₂ molecule

DIFFUSION

Barrier : 0.4 eV configuration / spin-polarized

Very likely !
This is diffusion !



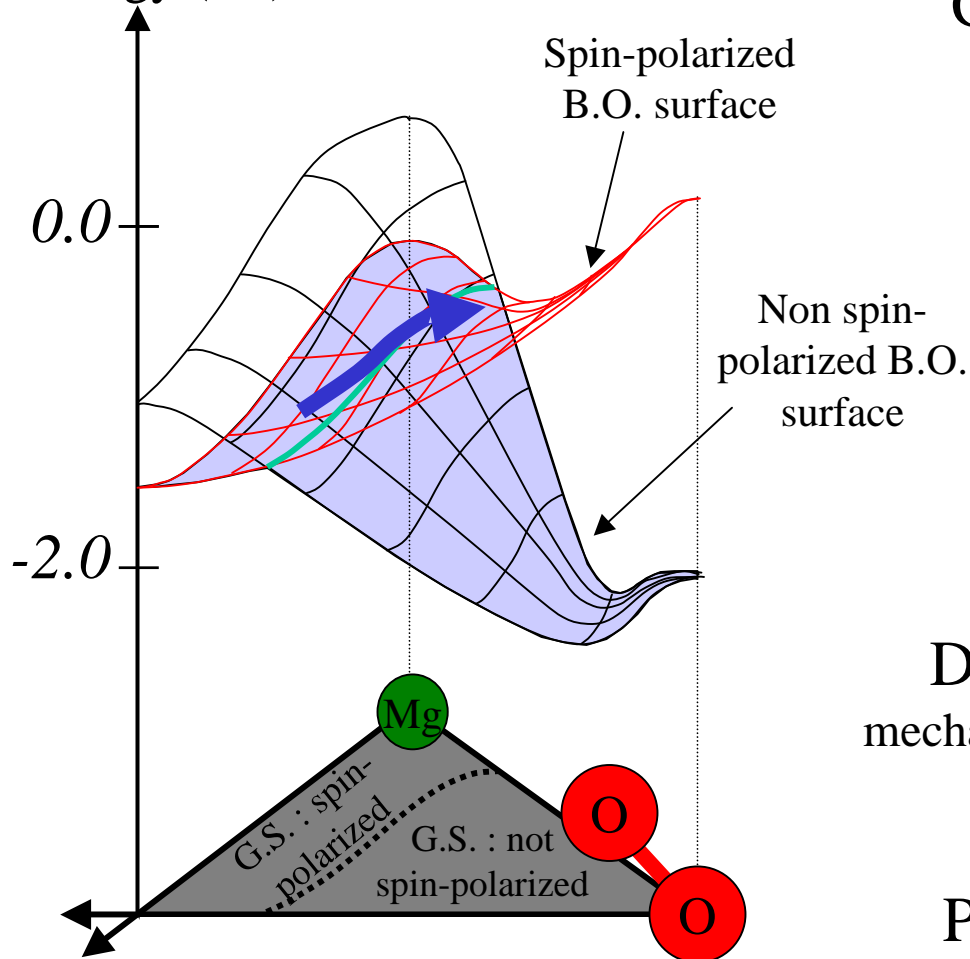
Isolated species : Mg atom, *O atom*, O₂ molecule

DIFFUSION

Spin-polarized oxygen diffuses

Non spin-polarized oxygen is fixed (peroxide ion O₂²⁻)

Total energy (eV)



Gaseous phase : O(S=1)



Adsorption
(spin-polarized surface)



Diffusion
(Barrier = 0.4 eV)



Desexcitation
mechanism? probability?



Peroxide ion
No more diffusion !

Isolated species : Mg atom, *O atom*, O₂ molecule

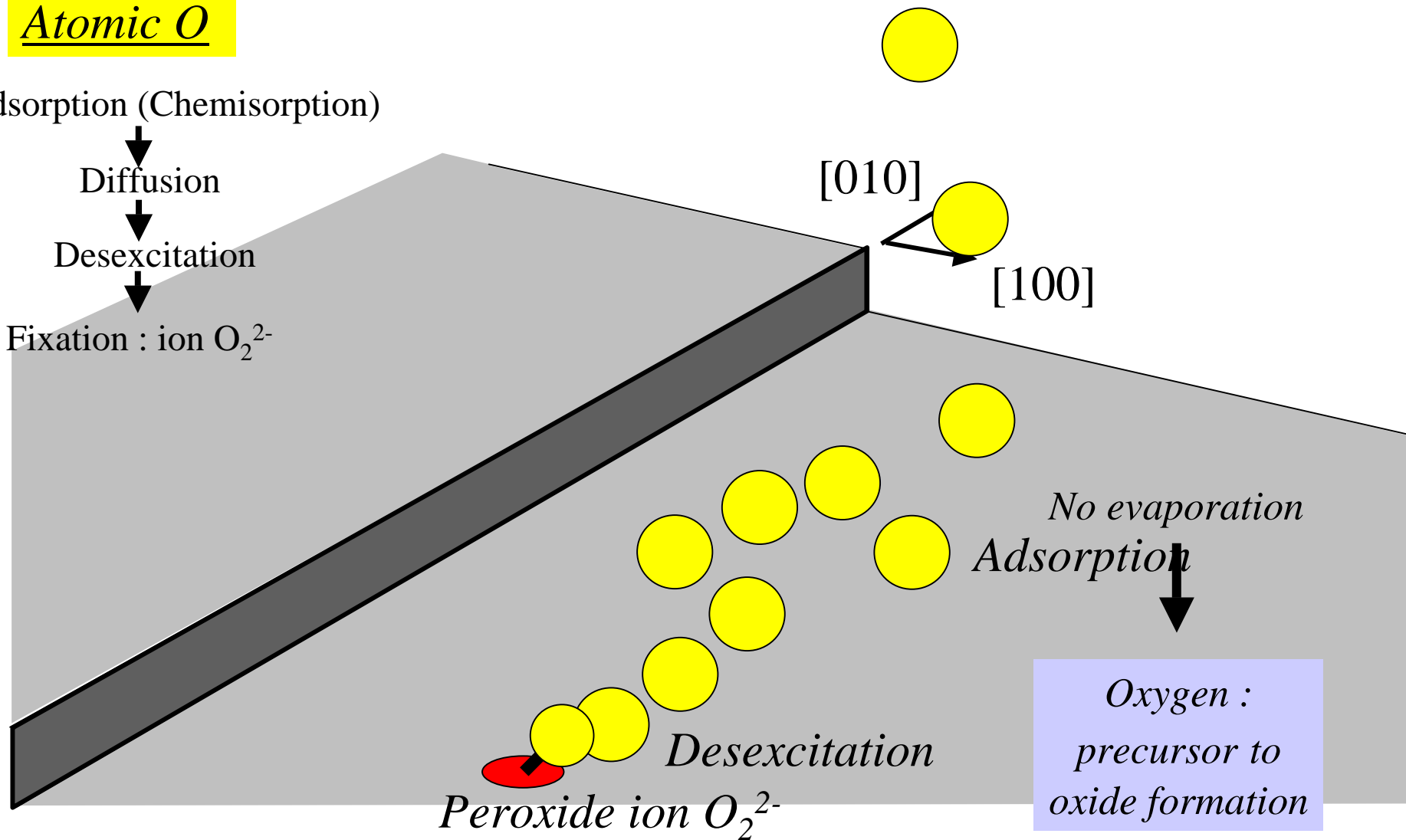
Atomic O

Adsorption (Chemisorption)

↓
Diffusion

↓
Desexcitation

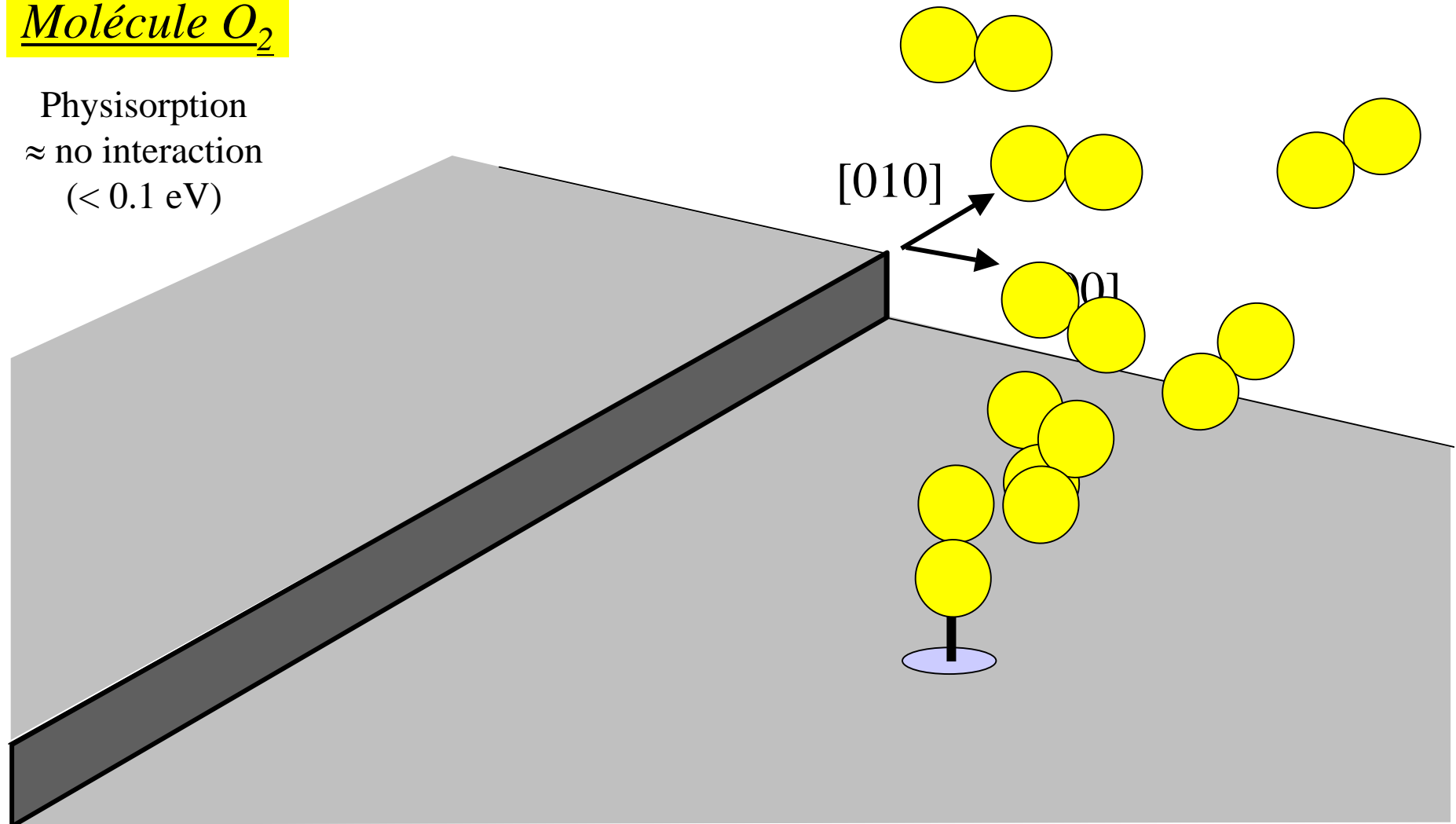
↓
Fixation : ion O₂²⁻



Isolated species : Mg atom, O atom, *O₂ molecule*

Molécule O₂

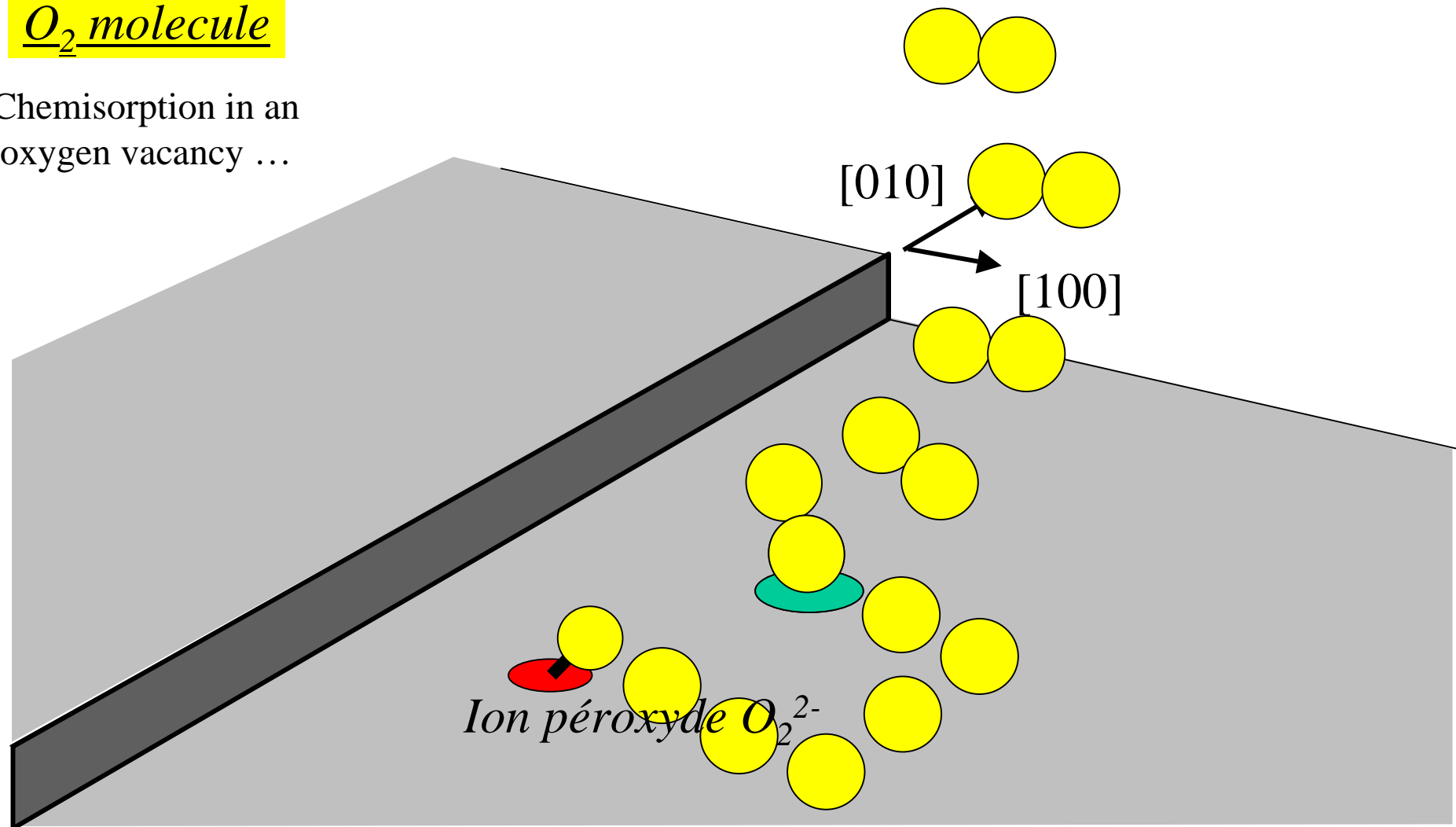
Physisorption
≈ no interaction
(< 0.1 eV)



Isolated species : Mg atom, O atom, *O₂ molecule*

O₂ molecule

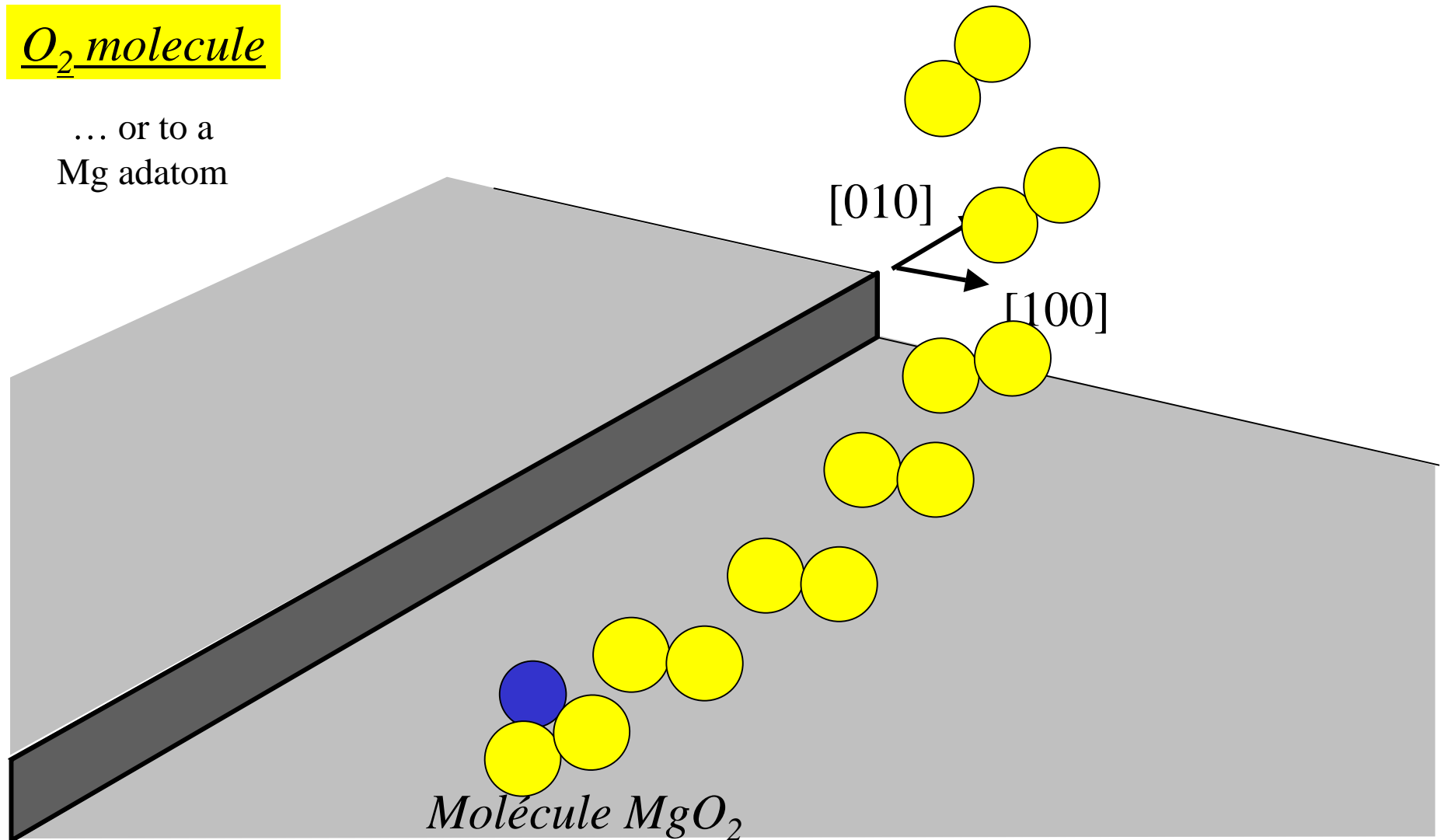
Chemisorption in an oxygen vacancy ...



Isolated species : Mg atom, O atom, ***O₂ molecule***

O₂ molecule

... or to a
Mg adatom



Isolated species : Mg atom, O atom, *O₂ molecule*

CONCLUSION

Gaseous oxygen (*O*, *O₂*)
+
MgO(001) surface, perfect
or with defects



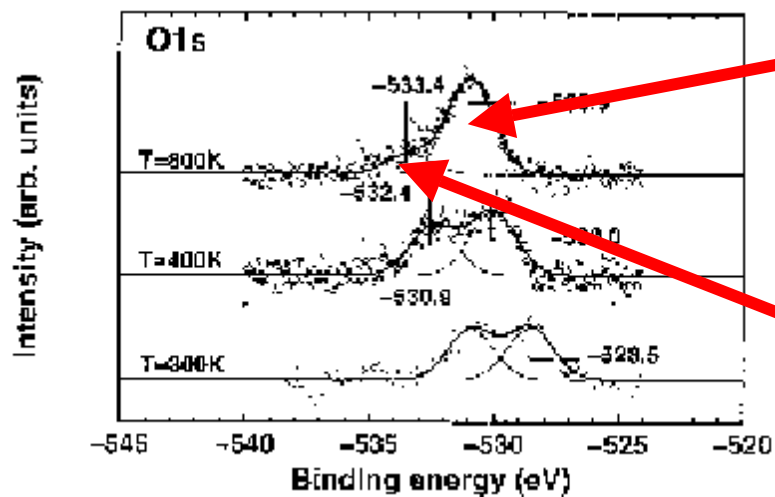
Peroxide ions *O₂²⁻*

O₂²⁻ & *O²⁻* : different oxidation degrees



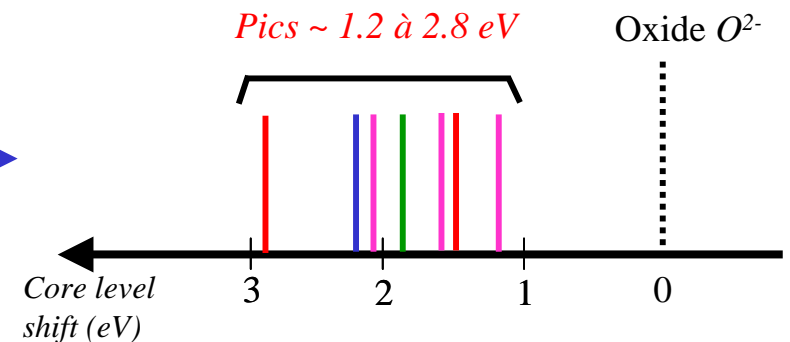
XPS measurements ?

Expérimental results : pic O 1s



D. Peterka et al., *Surf. Sci.* **431** (1999), 146

DFT simulation of XPS spectra :



⇒ the *peroxide ions*
may be responsible for
the observed shift

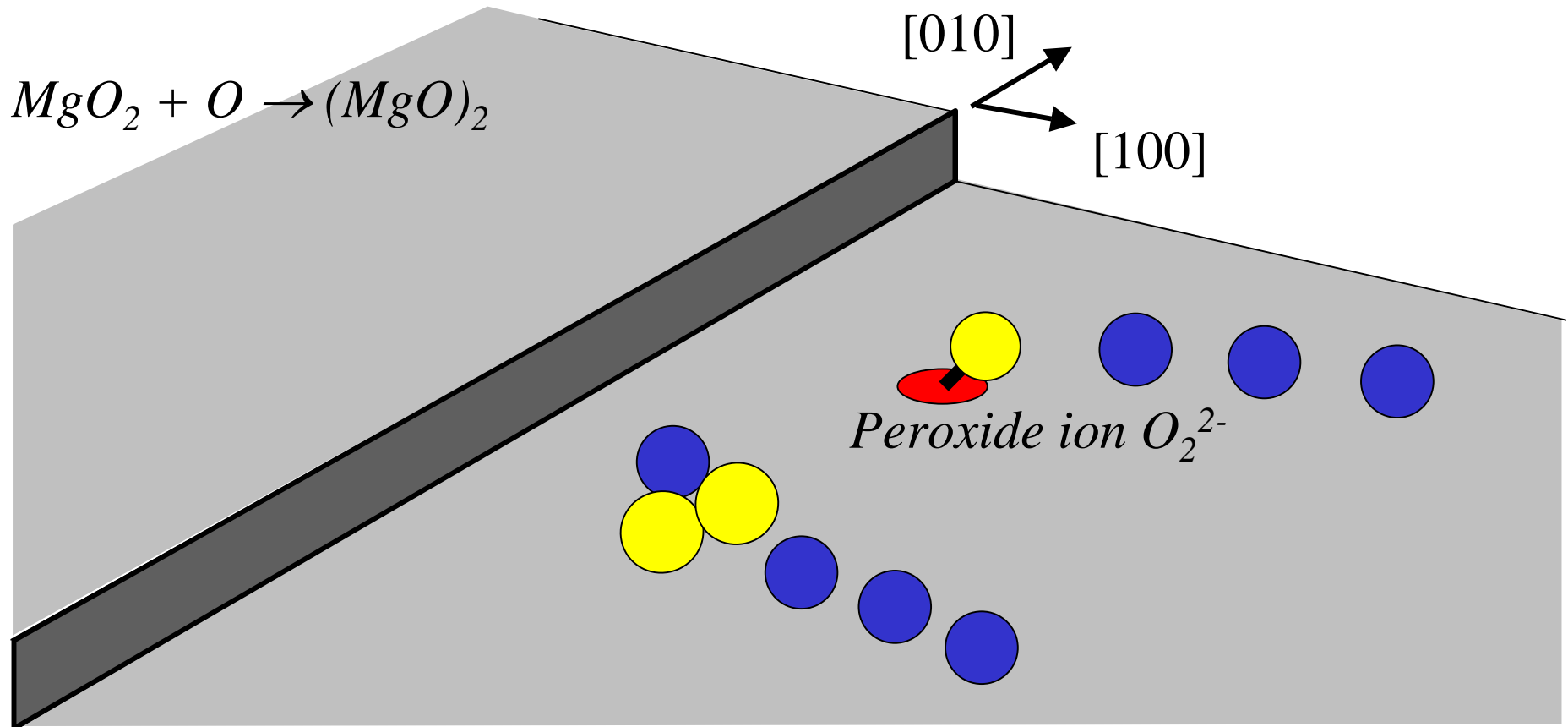
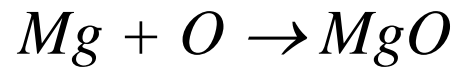
Overview

MgO growth : 3 phases

- 1 – Isolated species : Mg, O, O₂
- 2 – *Surface redox reactions***
- 3 – Nucleation phenomena

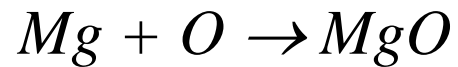
Surface redox reactions

Oxide formation : surface redox reaction

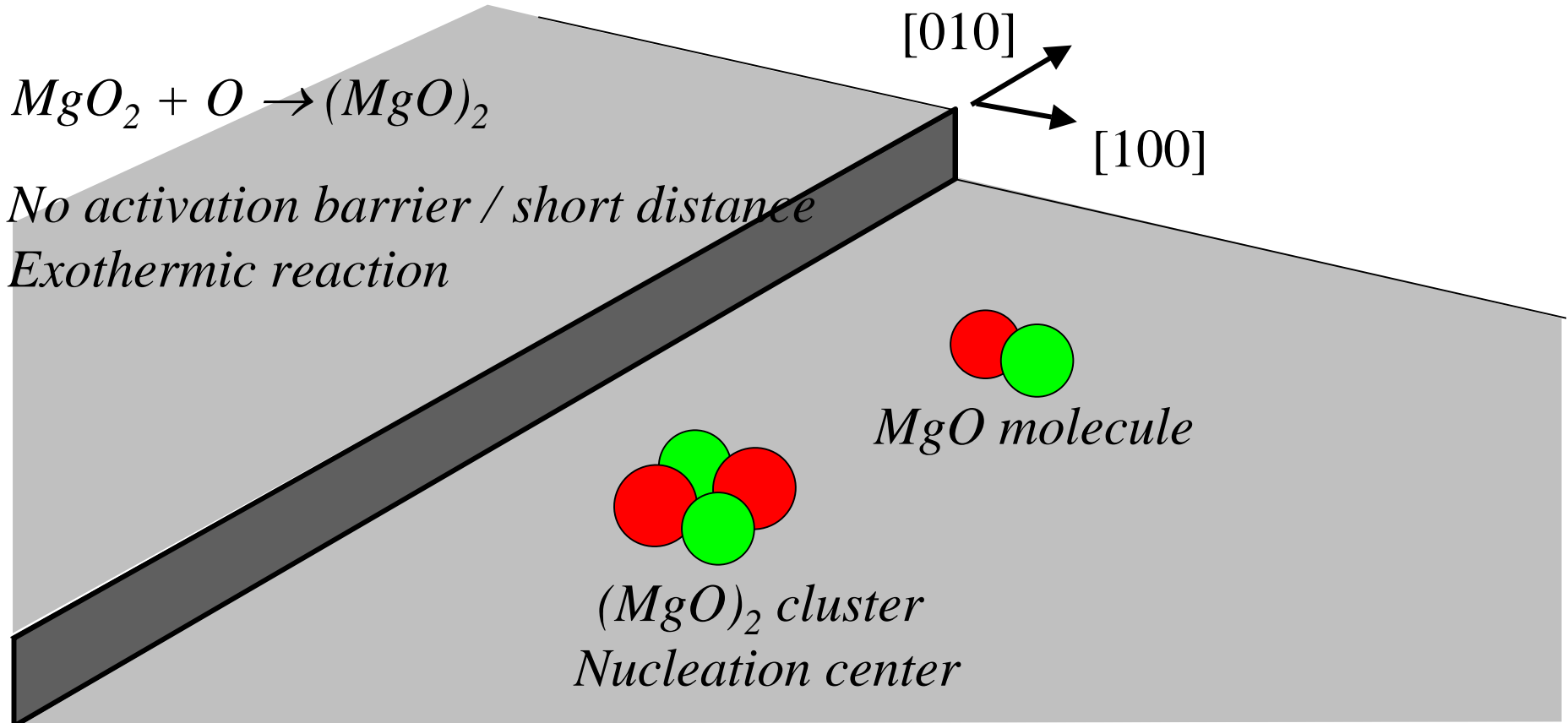


Surface redox reactions

Oxide formation : surface redox reaction

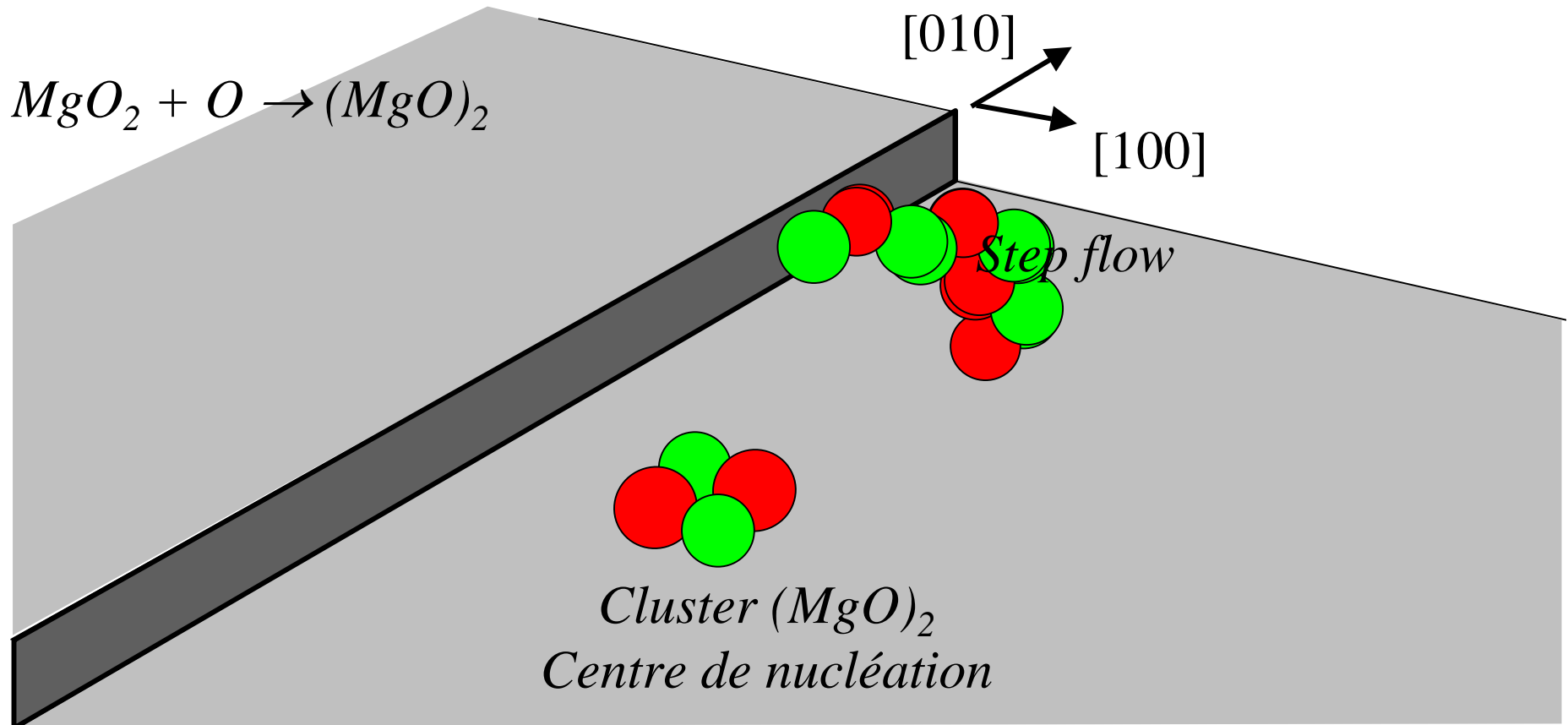
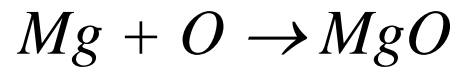


No activation barrier / short distance
Exothermic reaction



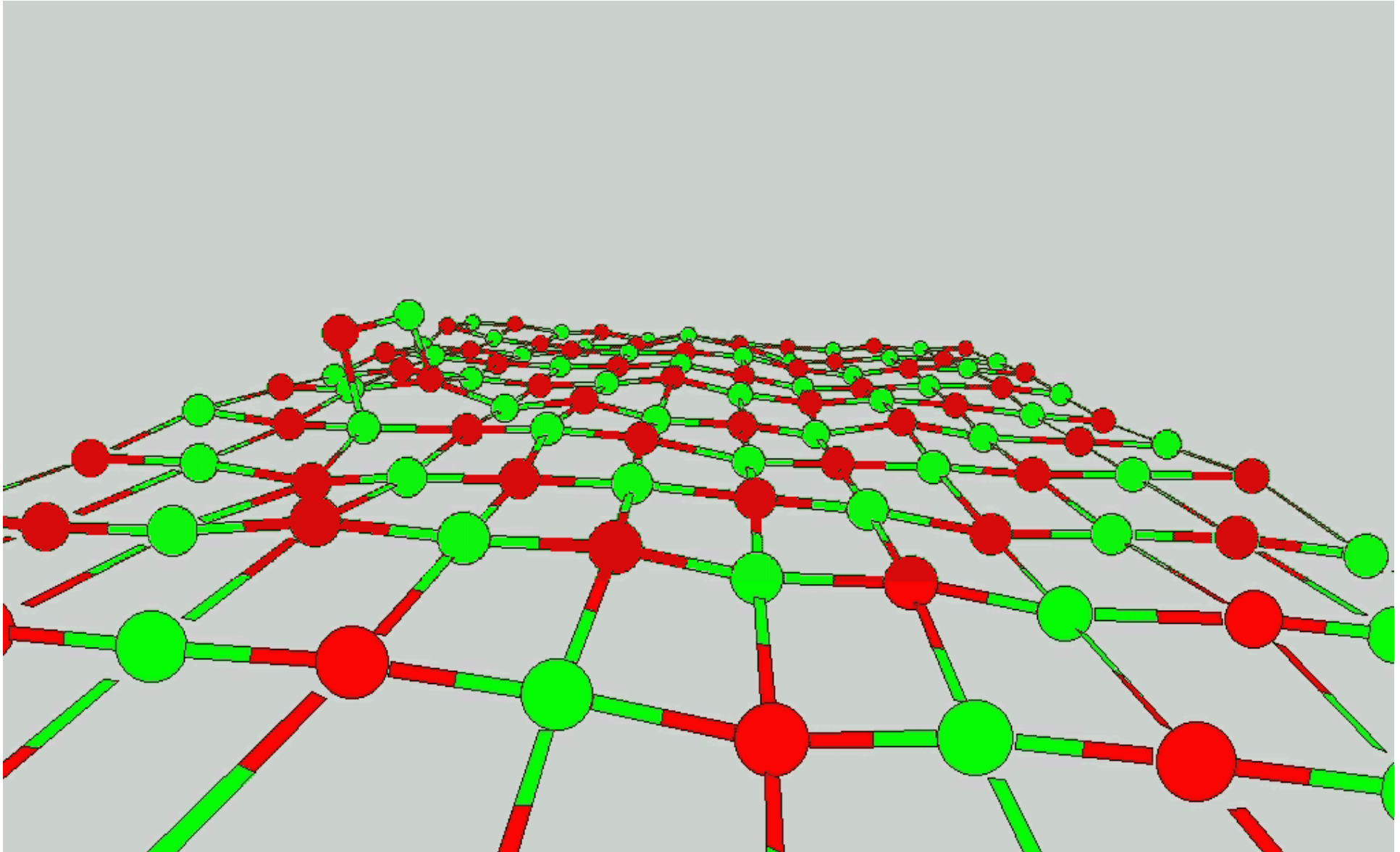
Surface redox reactions

Oxide formation : the MgO molecule



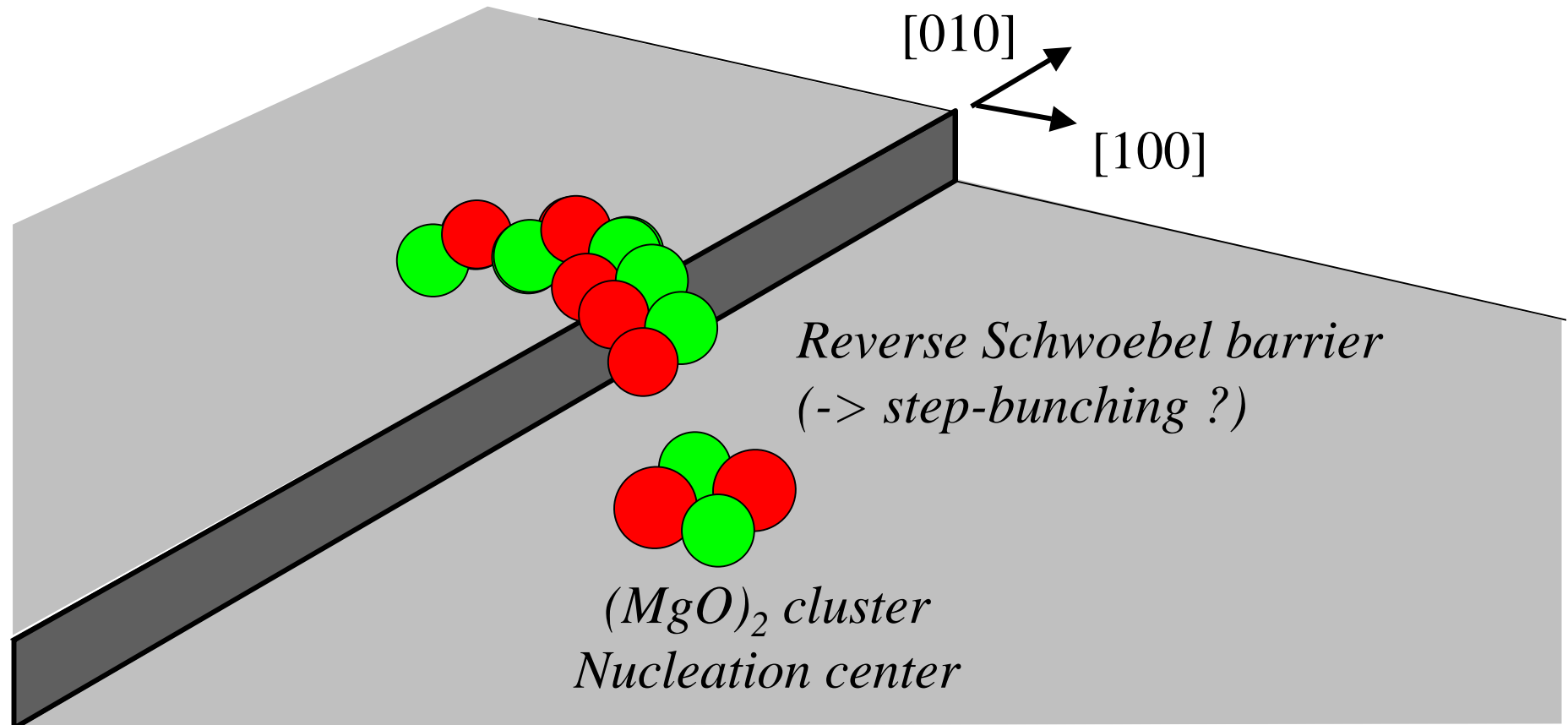
Surface redox reactions

Diffusion of the MgO molecule : Molecular Dynamics / $T = 1000\text{ K}$



Surface redox reactions

Oxide formation : the MgO molecule



Overview

MgO growth : 3 phases

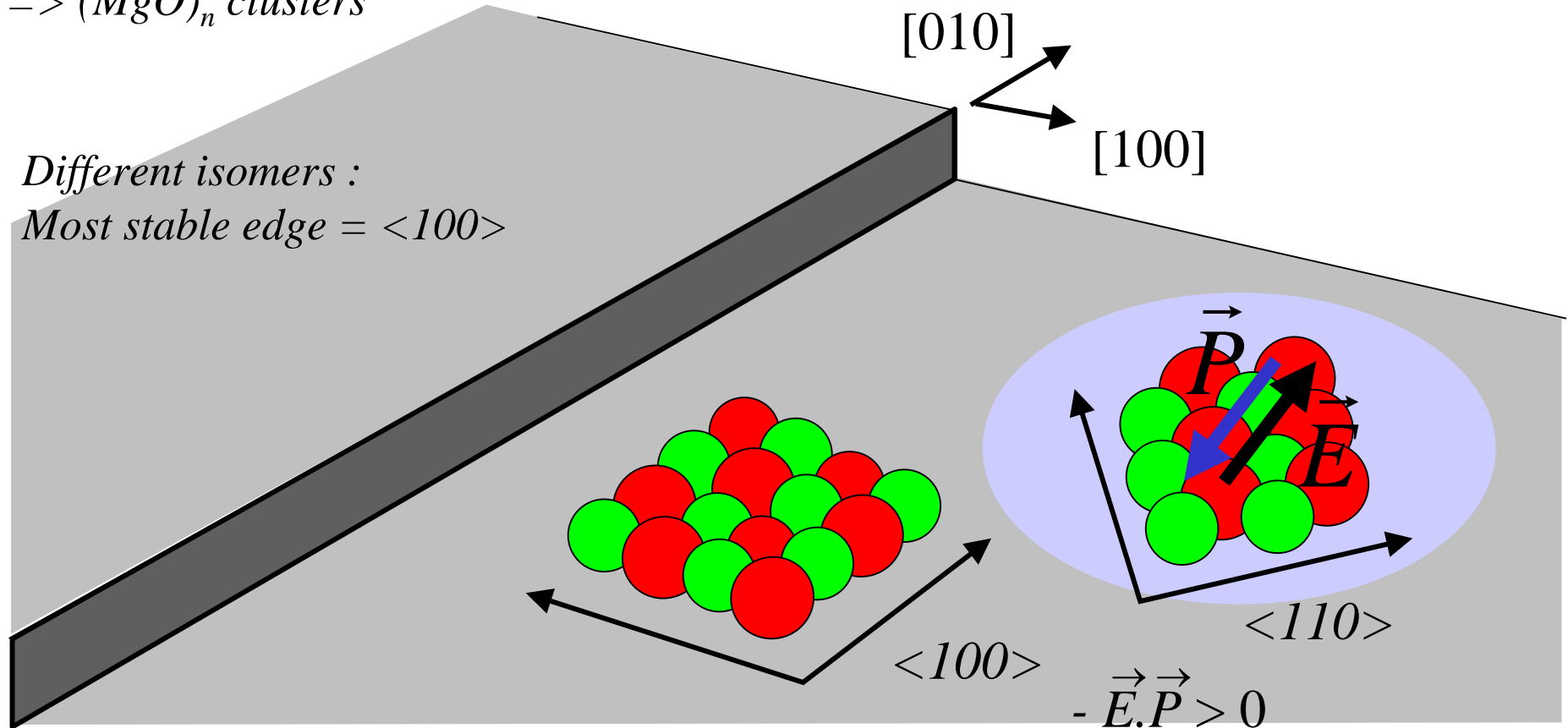
- 1 – Isolated species : Mg, O, O₂
- 2 – Surface redox reactions
- 3 – Nucleation phenomena***

Oxide nucleation

Stoichiometric clusters

Encounter of several MgO molecules
 $\Rightarrow (MgO)_n$ clusters

Different isomers :
Most stable edge = $\langle 100 \rangle$

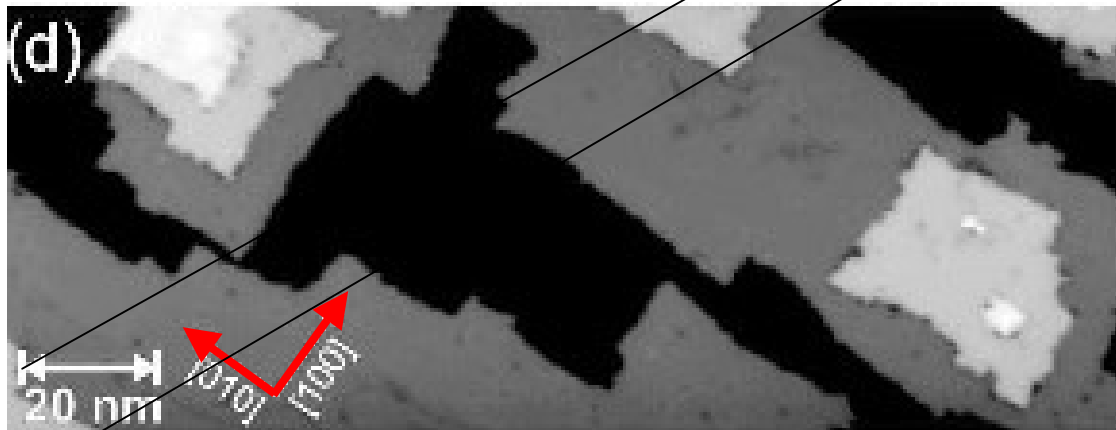


Oxide nucleation

Stoichiometric clusters / steps

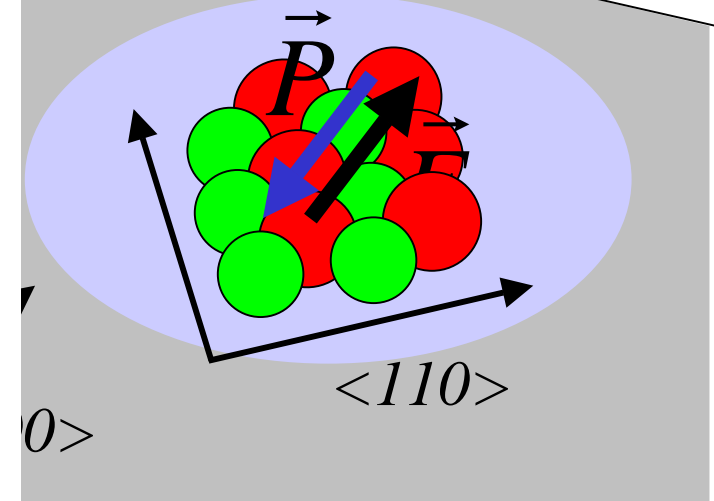
Encounter of several MgO molecules
 $\Rightarrow (MgO)_n$ clusters

The step direction is controlled
by electrostatics



[010]

[100]

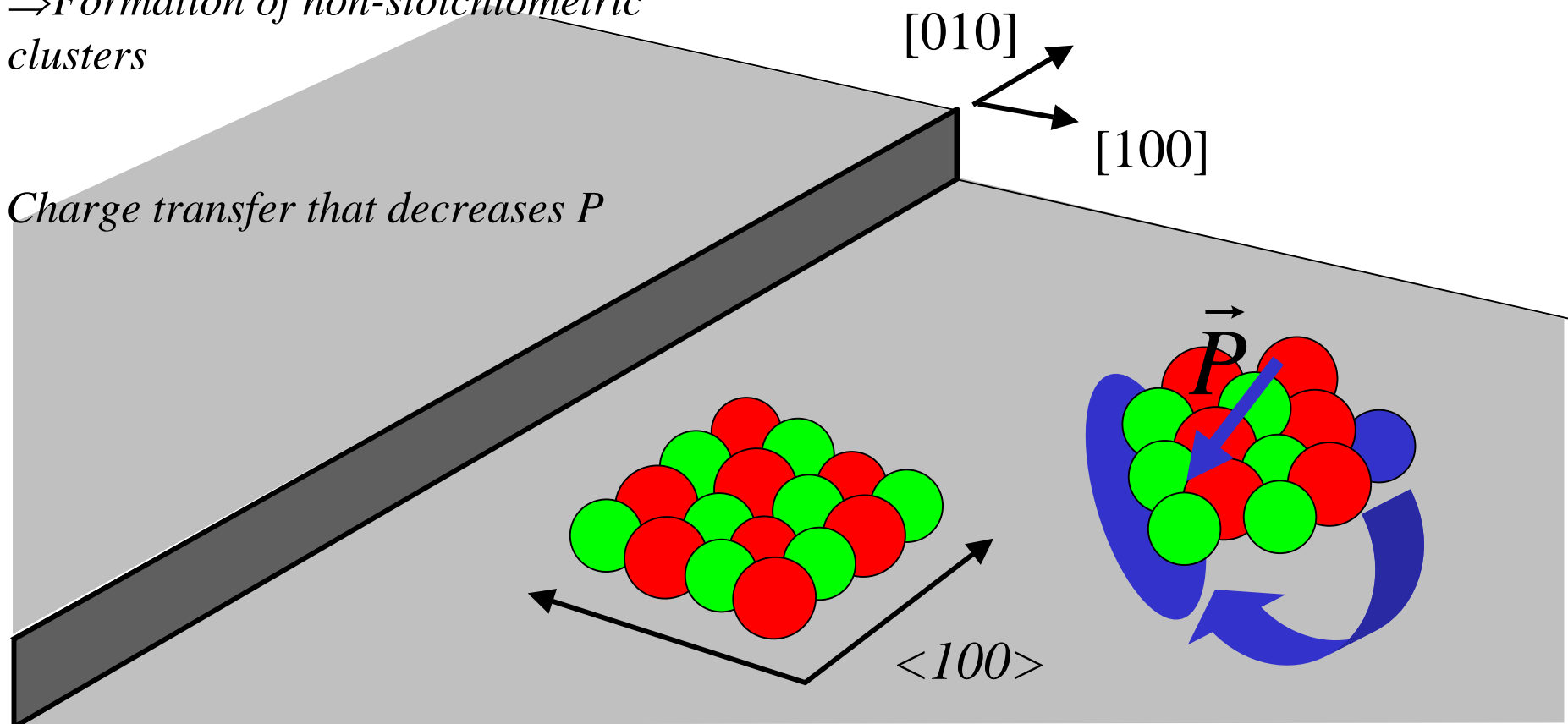


Oxide nucleation

« Polar » clusters :

Adsorption of Mg diffusing adatoms
⇒ Formation of non-stoichiometric
clusters

Charge transfer that decreases P



Oxide nucleation

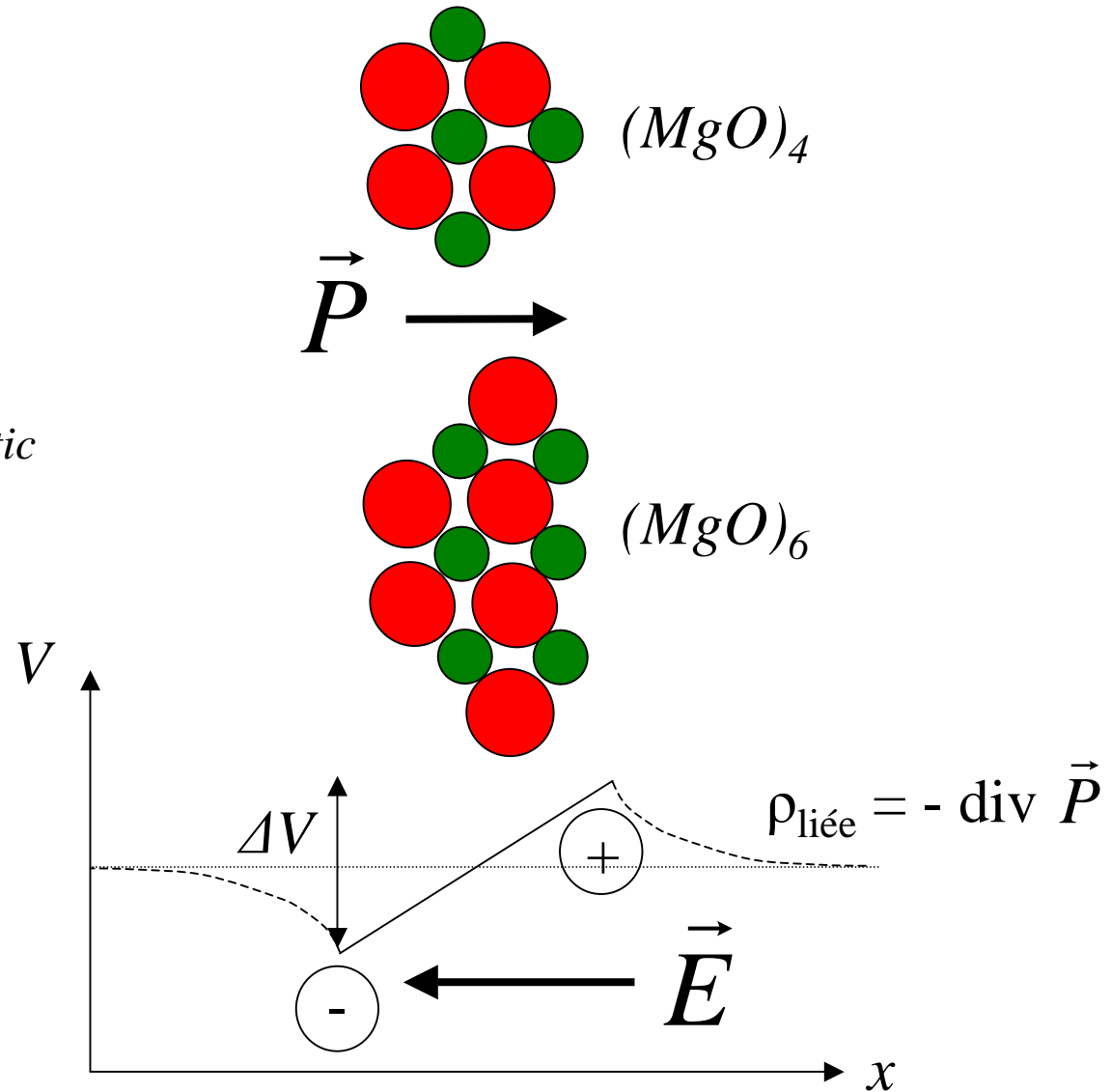
Mg adsorption at steps : the role of macroscopic fields

$P \Rightarrow$

- Surface density of charge

- Macroscopic electric field

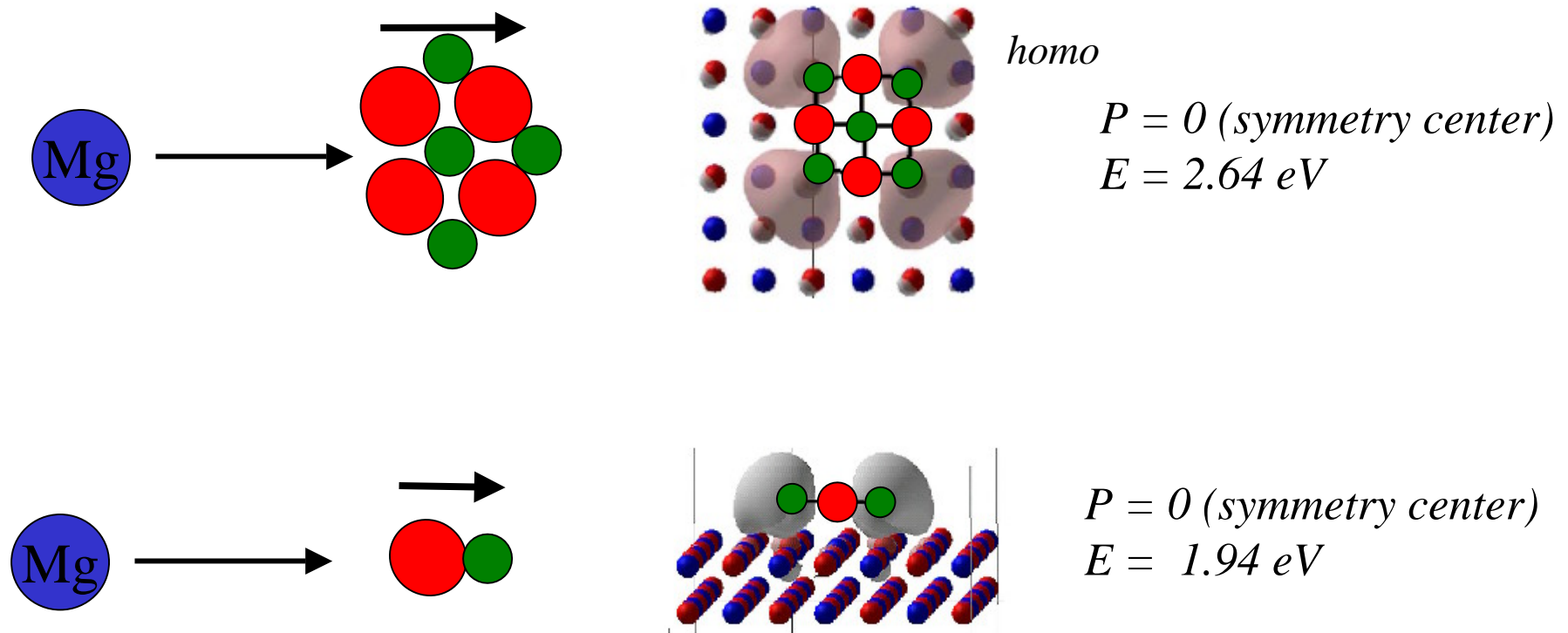
- ΔV : difference of electrostatic potential



Oxide nucleation

Mg adsorption at steps : the role of macroscopic fields

Adsorption in the low V region : Strong decrease in the dipole
Very strong Mg-cluster binding energy



Conclusion

1) *At the atomic scale : first idea of what can be the growth of an oxide*

Dynamics

- *Important surface diffusion :
Mg, MgO, O (ballistic)*
- *Schwoebel barriers : direct (Mg)
and reverse (MgO)*

Equilibrium :

- *Role of electrostatics
(step directions)*

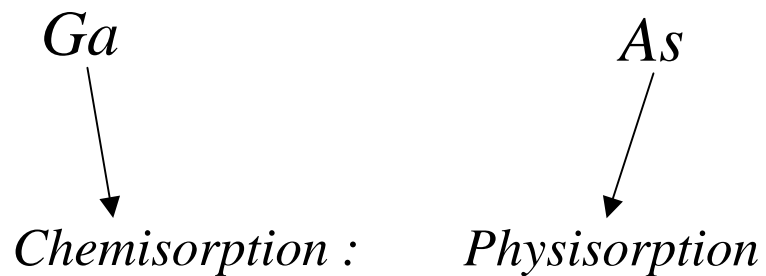
=> Possibility of a « step-flow » growth mode

2) *Microscopic parameters for a KMC simulation*

3) *Cf GaAs(110) vicinal surfaces : does an oxide surface spontaneously produce instabilities and nanostructures ?*

Conclusion

GaAs(110)



Diffuses

Diffuses

GaAs molecule

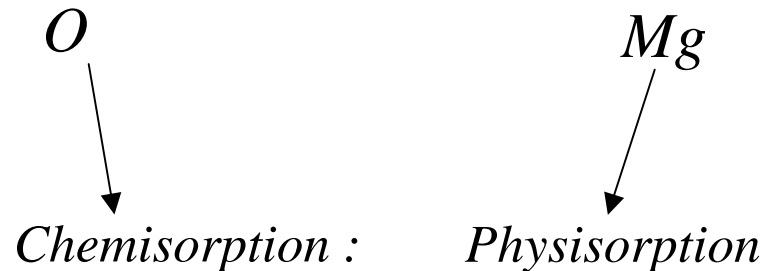
Diffuses

Direct Schwoebel barrier

Growth instabilities :

- *Step-bunching (low T)*
- *Step-meandering (High T)*

MgO(100)



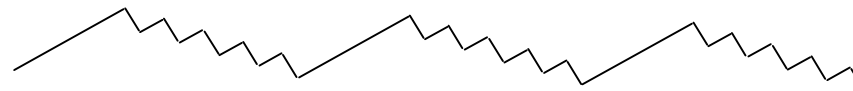
Does not diffuse

Diffuses

MgO molecule

Diffuses

Reverse Schwoebel barrier



? ... KMC !

Conclusion

1) *At the atomic scale : first idea of what can be the growth of an oxide*

Dynamics

- *Important surface diffusion :
Mg, MgO, O (ballistic)*
- *Schwoebel barriers : direct (Mg)
and reverse (MgO)*

Equilibre :

- *Role of electrostatics
(step directions)*

=> *Possibility of a « step-flow » growth mode*

2) *Microscopic parameters for a KMC simulation*

3) *Cf GaAs(110 vicinal surfaces : does an oxide surface spontaneously produce instabilities and nanostructures ?*



Reverse Schwoebel barrier => STEP-BUNCHING instability

... complex ! (different species, redox reactions, electrostatics)

Ce document à été crée avec Win2pdf disponible à <http://www.win2pdf.com/fr>
La version non enregistrée de Win2pdf est uniquement pour évaluation ou à usage non commercial.